

The S-75V00ANC is a single 2-Input NAND Gate fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve ultra high speed operation correspond to LSTTL IC's.

All gates of the internal circuitry have buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 5 V to 3 V and battery backup applications.

■ Features

- Wide power supply range: 2 V to 5.5 V
- Low current consumption: 1.0 μ A max. (at 5.5 V, 25°C)
- Typical propagation delay: $t_{PD} = 3.7$ ns (at 5 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

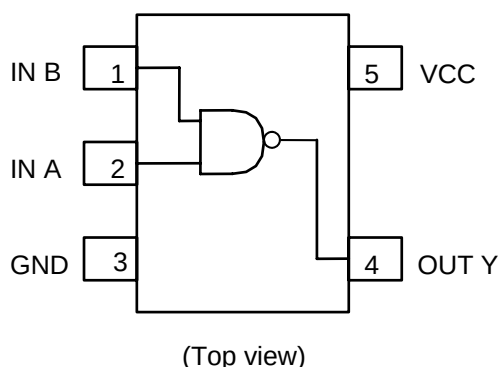
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

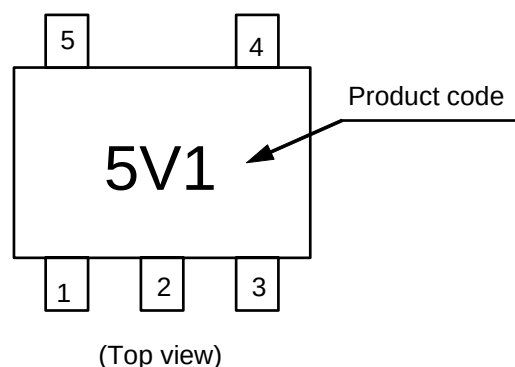
■ Package

- SC-88A

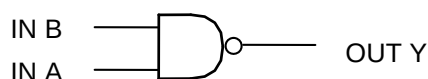
■ Pin Configuration



■ Marking Specification



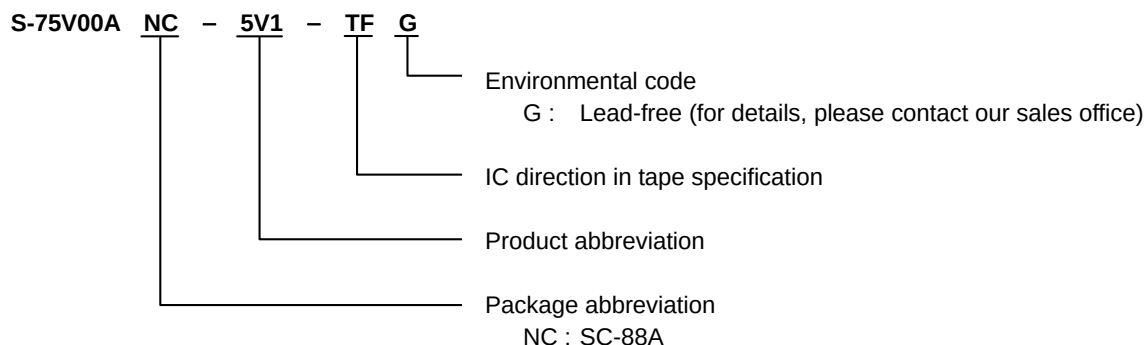
■ Logic Diagram



True values

A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

■ Product Name Structure



■ Absolute Maximum Ratings

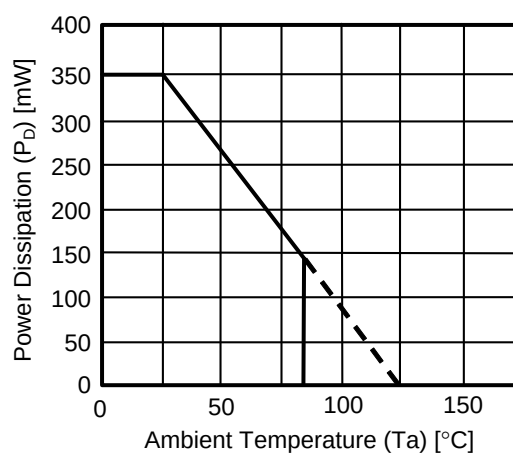
(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +7.0	V
Input voltage	V_{IN}	-0.5 to +7.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±25	mA
V_{CC} /GND current	I_{CC}	±50	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

*1. When mounted on board
[Mounted board]

- (1) Board size : 114.3 mm × 76.2 mm × 1.6 mm
(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	2 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 100 ($V_{CC} = 3.3 \pm 0.3$ V)	ns
		0 to 20 ($V_{CC} = 5 \pm 0.5$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit		
					V _{CC}	Min.	Typ.	Max.	Min.		Max.	
Input voltage	“H” level	V _{IH}	—	2.0	1.5	—	—	1.5	—	V		
				3 to 5.5	V _{CC} ×0.7	—	—	V _{CC} ×0.7	—	V		
	“L” level	V _{IL}	—	2.0	—	—	0.5	—	0.5	V		
				3 to 5.5	—	—	V _{CC} ×0.3	—	V _{CC} ×0.3	V		
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IL} or V _{IH}	I _{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
					4.5	4.4	4.5	—	4.4	—	V	
				I _{OH} = −4 mA	3.0	2.58	—	—	2.48	—	V	
					I _{OH} = −8 mA	4.5	3.94	—	—	3.80	—	V
						—	—	—	—	—	—	—
	“L” level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA	2.0	—	0	0.1	—	0.1	V	
					3.0	—	0	0.1	—	0.1	V	
					4.5	—	0	0.1	—	0.1	V	
				I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	V	
					I _{OL} = 8 mA	4.5	—	—	0.36	—	0.44	V
Input current		I _{IN}	V _{IN} = 5.5 V or GND	0 to 5.5	—	—	±0.1	—	±1.0	μA		
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	1.0	—	10.0	μA		

■ AC Electrical Characteristics

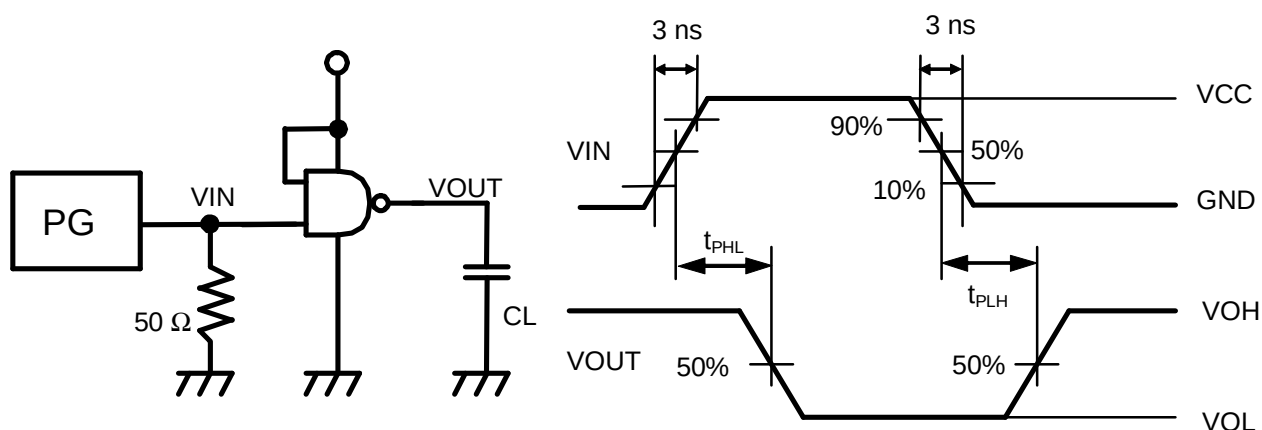
(Input $t_R = t_F = 3$ ns unless otherwise specified)

Item	Symbol	Measurement Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit	
		V _{CC} (V)	C _L (pF)	Min.	Typ.	Max.	Min.	Max.		
Propagation delay time	t _{PLH} , t _{PHL}	—	3.3±0.3	15	—	5.5	7.9	1.0	9.5	ns
				50	—	10.0	14.0	1.0	15.0	ns
			5.0±0.5	15	—	3.7	5.5	1.0	6.5	ns
				50	—	6.1	8.5	1.0	9.0	ns
Input capacitance	C _{IN}	—		—	4	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—		—	14	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

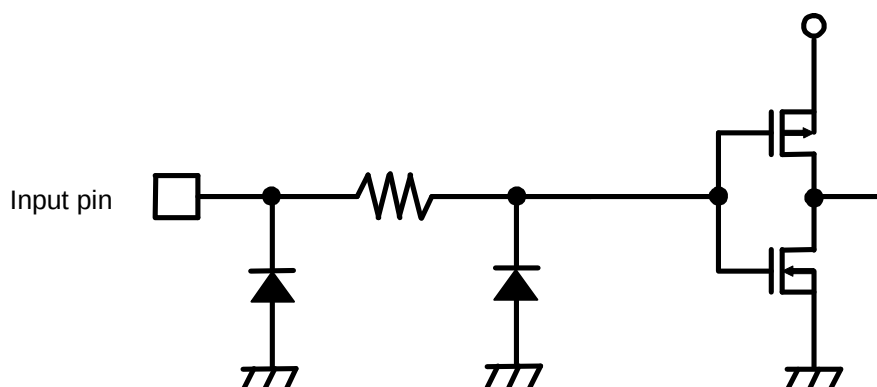
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75V02ANC is a single 2-input NOR gate fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve ultra high speed operation correspond to LSTTL IC's.

All gates of the internal circuitry have buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 5 V to 3 V and battery backup applications.

■ Features

- Wide power supply range: 2 V to 5.5 V
- Low current consumption: 1.0 μ A max. (at 5.5 V, 25°C)
- Typical propagation delay: $t_{PD} = 3.6$ ns (at 5 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

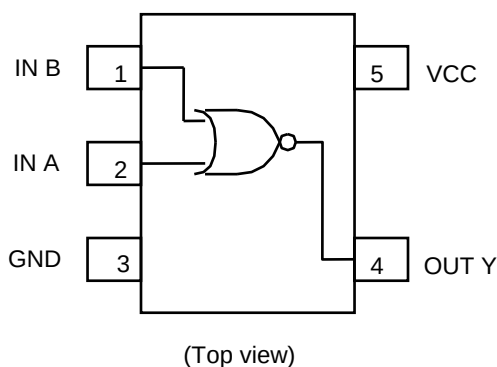
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

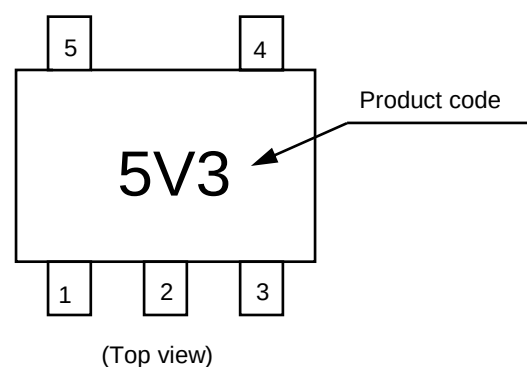
■ Package

- SC-88A

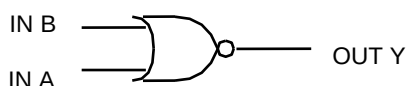
■ Pin Configuration



■ Marking Specification



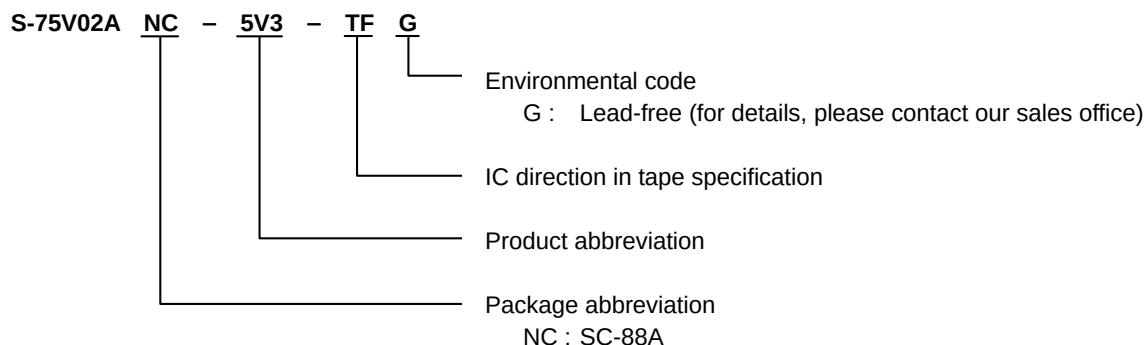
■ Logic Diagram



True values

A	B	Y
L	L	H
L	H	L
H	L	L
H	H	L

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +7.0	V
Input voltage	V_{IN}	-0.5 to +7.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±25	mA
V_{CC} /GND current	I_{CC}	±50	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

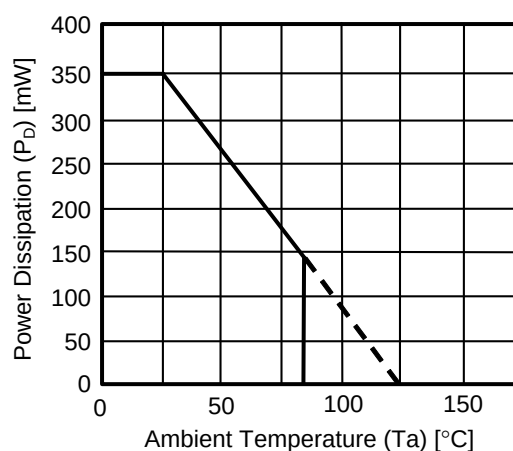
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

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Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	2 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 100 ($V_{CC} = 3.3 \pm 0.3$ V)	ns
		0 to 20 ($V_{CC} = 5 \pm 0.5$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit		
					V _{CC}	Min.	Typ.	Max.	Min.		Max.	
Input voltage	“H” level	V _{IH}	—	2.0	1.5	—	—	1.5	—	V		
				3 to 5.5	V _{CC} ×0.7	—	—	V _{CC} ×0.7	—	V		
	“L” level	V _{IL}	—	2.0	—	—	0.5	—	0.5	V		
				3 to 5.5	—	—	V _{CC} ×0.3	—	V _{CC} ×0.3	V		
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IL}	I _{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
					4.5	4.4	4.5	—	4.4	—	V	
				I _{OH} = −4 mA	3.0	2.58	—	—	2.48	—	V	
					I _{OH} = −8 mA	4.5	3.94	—	—	3.80	—	V
	“L” level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	—	0	0.1	—	0.1	V	
					3.0	—	0	0.1	—	0.1	V	
					4.5	—	0	0.1	—	0.1	V	
				I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	V	
					I _{OL} = 8 mA	4.5	—	—	0.36	—	0.44	V
						Input current		I _{IN}	V _{IN} = 5.5 V or GND	0 to 5.5	—	—
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	1.0	—	10.0	μA		

■ AC Electrical Characteristics

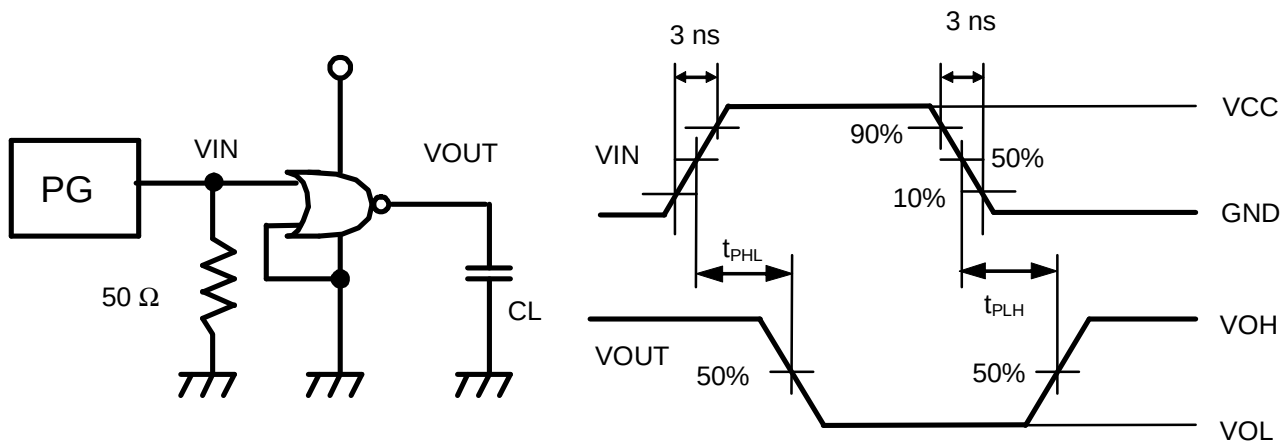
(Input $t_R = t_F = 3$ ns unless otherwise specified)

Item	Symbol	Measurement Conditions			Ta = 25°C			Ta = −40 to 85°C		Unit
			V _{CC} (V)	C _L (pF)	Min.	Typ.	Max.	Min.	Max.	
Propagation delay time	t _{PLH} , t _{PHL}	—	3.3±0.3	15	—	5.6	7.9	1.0	9.5	ns
				50	—	10.0	14.0	1.0	15.0	ns
			5.0±0.5	15	—	3.6	5.5	1.0	6.5	ns
				50	—	5.7	8.0	1.0	9.0	ns
Input capacitance	C _{IN}	—			—	4	10	—	10	pF
Equivalent internal capacitance	C _{PD} ^{*1}	—			—	15	—	—	—	pF

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

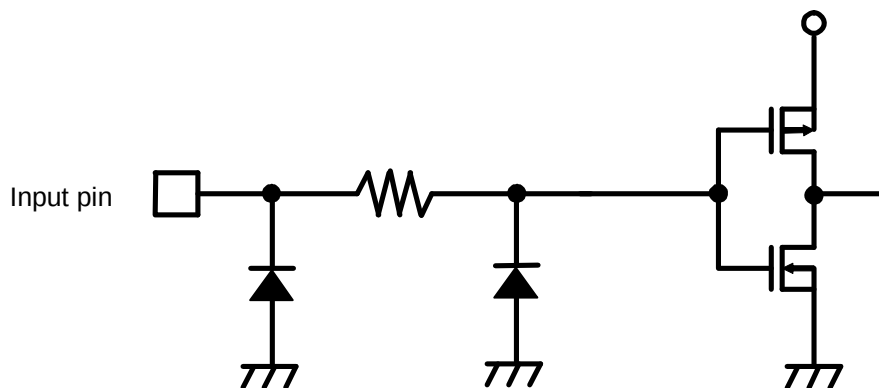
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75V04ANC is a INVERTER fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve ultra high speed operation correspond to LSTTL IC's.

The special purpose unbuffered circuit design is suitable for a wide variety of linear circuits.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 5 V to 3 V and battery backup applications.

■ Features

- Wide power supply range: 2 V to 5.5 V
- Low current consumption: 1.0 μ A max. (at 5.5 V, 25°C)
- Typical propagation delay: $t_{PD} = 3.8$ ns (at 5 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

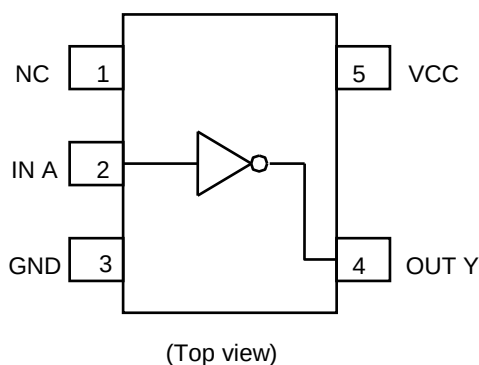
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

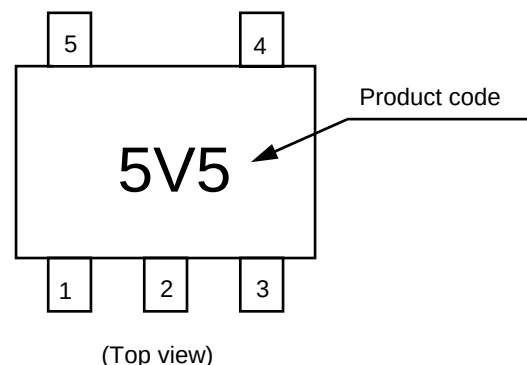
■ Package

- SC-88A

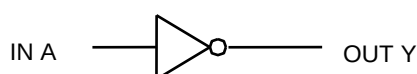
■ Pin Configuration



■ Marking Specification



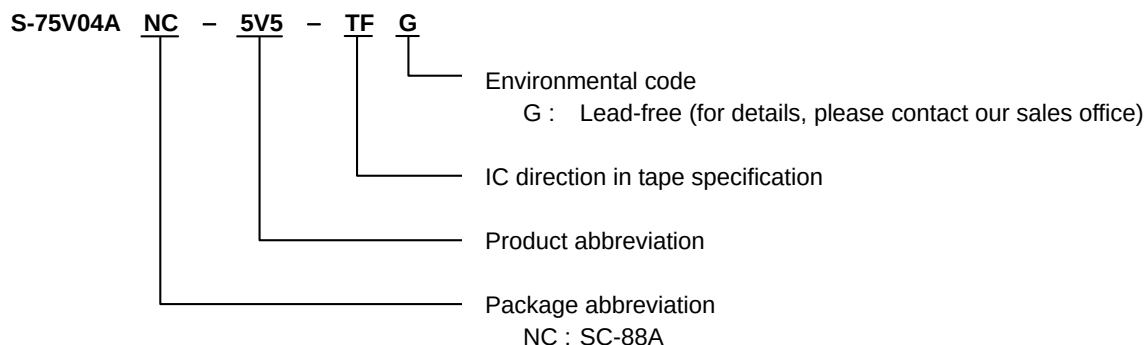
■ Logic Diagram



True values

A	Y
L	H
H	L

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +7.0	V
Input voltage	V_{IN}	-0.5 to +7.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±25	mA
V_{CC} /GND current	I_{CC}	±50	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

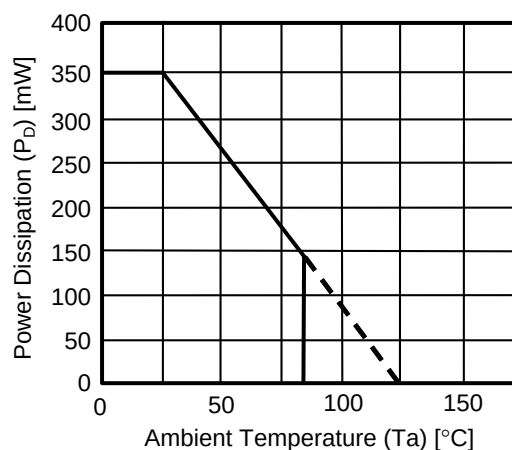
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

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Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	2 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 100 ($V_{CC} = 3.3 \pm 0.3$ V)	ns
		0 to 20 ($V_{CC} = 5 \pm 0.5$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		V _{CC}	Ta = 25°C			Ta = −40 to 85°C		Unit	
					Min.	Typ.	Max.	Min.	Max.			
Input voltage	“H” level	V _{IH}	—		2.0	1.5	—	—	1.5	—	V	
					3 to 5.5	V _{CC} ×0.7	—	—	V _{CC} ×0.7	—	V	
	“L” level	V _{IL}	—		2.0	—	—	0.5	—	0.5	V	
					3 to 5.5	—	—	V _{CC} ×0.3	—	V _{CC} ×0.3	V	
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IL}	I _{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
					4.5	4.4	4.5	—	4.4	—	V	
				I _{OH} = −4 mA	3.0	2.58	—	—	2.48	—	V	
					I _{OH} = −8 mA	4.5	3.94	—	—	3.80	—	V
	“L” level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA	2.0	—	0	0.1	—	0.1	V	
					3.0	—	0	0.1	—	0.1	V	
					4.5	—	0	0.1	—	0.1	V	
				I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	V	
					I _{OL} = 8 mA	4.5	—	—	0.36	—	0.44	V
Input current		I _{IN}	V _{IN} = 5.5 V or GND	0 to 5.5	—	—	±0.1	—	±1.0	μA		
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	1.0	—	10.0	μA		

■ AC Electrical Characteristics

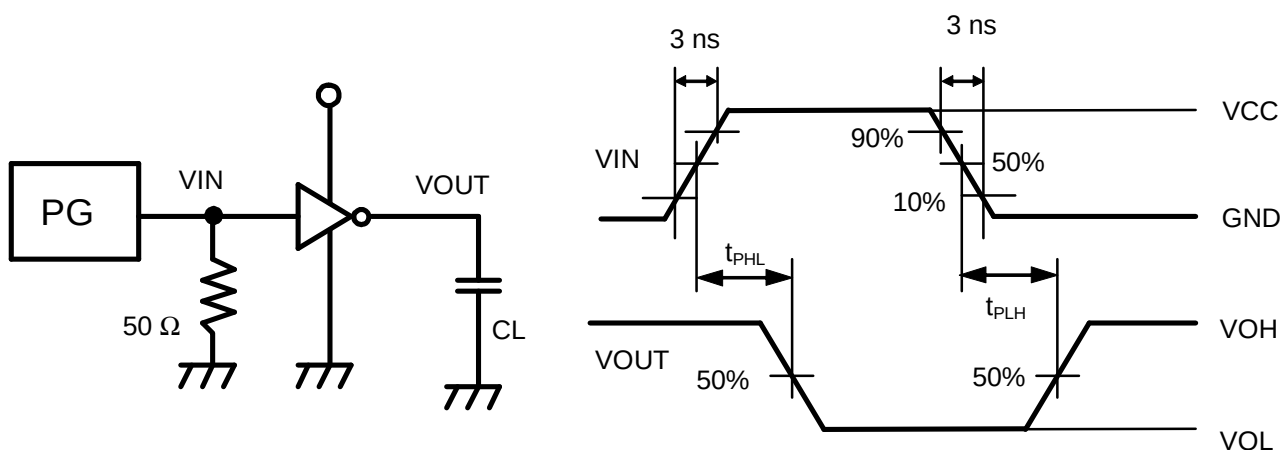
(Input $t_R = t_F = 3$ ns unless otherwise specified)

Item	Symbol	Measurement Conditions		Ta = 25°C			Ta = -40 to 85°C		Unit	
		V _{CC} (V)	C _L (pF)	Min.	Typ.	Max.	Min.	Max.		
Propagation delay time	t _{PLH} , t _{PHL}	—	3.3±0.3	15	—	5.0	7.1	1.0	8.5	ns
				50	—	9.6	13.5	1.0	14.5	ns
			5.0±0.5	15	—	3.8	5.5	1.0	6.5	ns
				50	—	5.7	8.0	1.0	9.0	ns
Input capacitance	C _{IN}	—		—	4	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—		—	13	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
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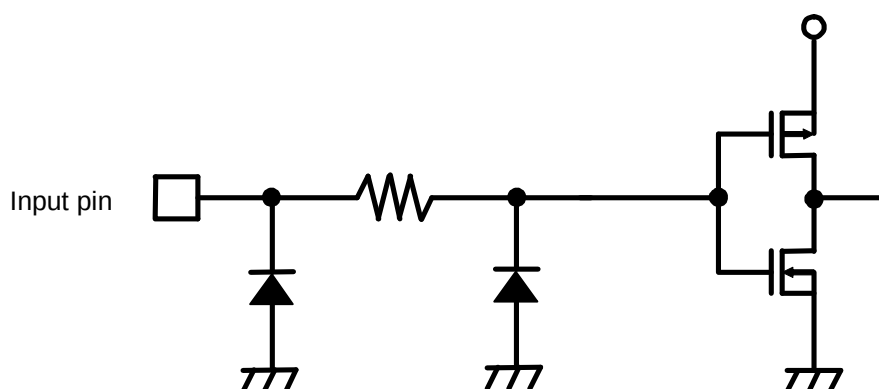
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75VU04ANC is an inverter fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve ultra high speed operation correspond to LSTTL IC's.

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- Low current consumption: 1.0 μ A max. (at 5.5 V, 25°C)
- Typical propagation delay: $t_{PD} = 3.5$ ns (at 5 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 10\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

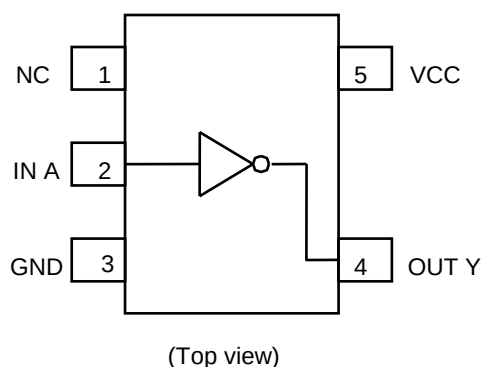
■ Applications

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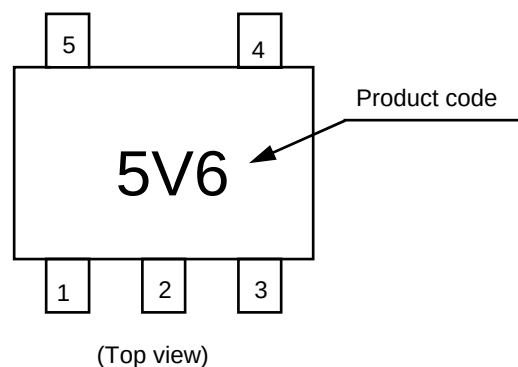
■ Package

- SC-88A

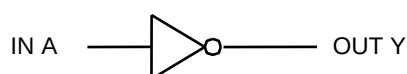
■ Pin Configuration



■ Marking Specification



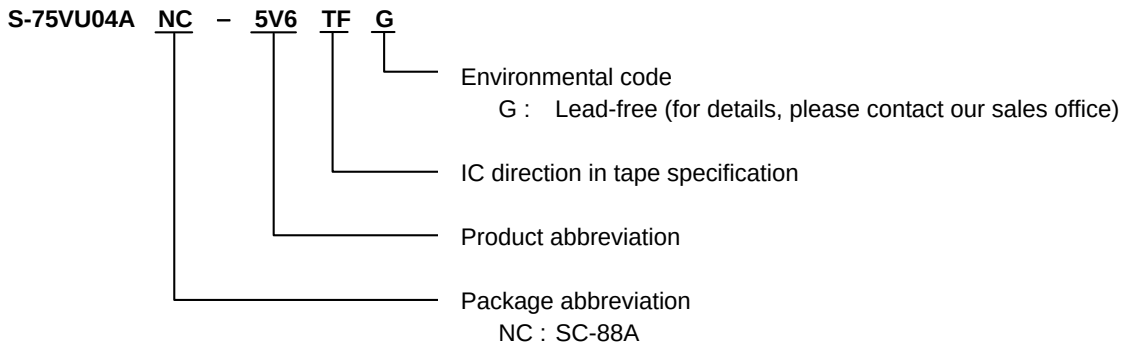
■ Logic Diagram



True values

A	Y
L	H
H	L

■ Product Name Structure



■ Absolute Maximum Ratings

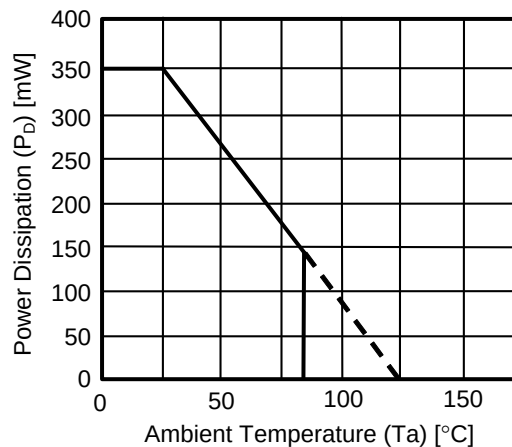
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Item	Symbol	Absolute Maximum Ratings	Unit
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Input voltage	V_{IN}	-0.5 to +7.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±25	mA
V_{CC} /GND current	I_{CC}	±50	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

*1. When mounted on board
[Mounted board]

- (1) Board size : 114.3 mm × 76.2 mm × t1.6 mm
- (2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	2 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V

■ DC Electrical Characteristics

Item		Symbol	Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit	
					V _{CC}	Min.	Typ.	Max.	Min.		Max.
Input voltage	“H” level	V _{IH}	V _{OUT} = V _{OL}	2.0	1.7	—	—	1.7	—	V	
				3 to 5.5	V _{CC} ×0.8	—	—	V _{CC} ×0.8	—	V	
	“L” level	V _{IL}	V _{OUT} = V _{OH}	2.0	—	—	0.3	—	0.3	V	
				3 to 5.5	—	—	V _{CC} ×0.2	—	V _{CC} ×0.2	V	
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IL} I _{OH} = −50 μA	2.0	1.8	2.0	—	1.8	—	V	
				3.0	2.7	3.0	—	2.7	—	V	
				4.5	4.0	4.5	—	4.0	—	V	
		V _{IN} = GND		I _{OH} = −4 mA	3.0	2.58	—	—	2.48	—	V
				I _{OH} = −8 mA	4.5	3.94	—	—	3.80	—	V
	“L” level	V _{OL}	V _{IN} = V _{IH} I _{OL} = 50 μA	2.0	—	0	0.2	—	0.2	V	
				3.0	—	0	0.3	—	0.3	V	
				4.5	—	0	0.5	—	0.5	V	
		V _{IN} = V _{CC}	I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	V	
			I _{OL} = 8 mA	4.5	—	—	0.36	—	0.44	V	
Input current		I _{IN}	V _{IN} = 5.5 V or GND	0 to 5.5	—	—	±0.1	—	±1.0	μA	
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	1.0	—	10.0	μA	

■ AC Electrical Characteristics

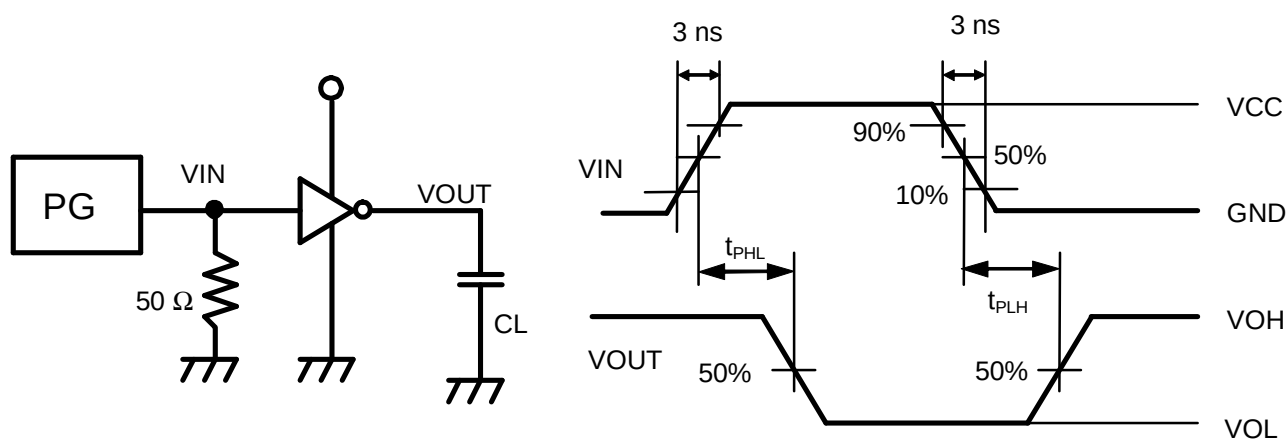
(Input $t_R = t_F = 3$ ns unless otherwise specified)

(Input $t_r = t_f = 5$ ns unless otherwise specified)										
Item	Symbol	Measurement Conditions		Ta = 25°C			Ta = -40 to 85°C		Unit	
		V _{CC} (V)	C _L (pF)	Min.	Typ.	Max.	Min.	Max.		
Propagation delay time	t _{PLH} , t _{PHL}	—	3.3±0.3	15	—	5.0	8.9	1.0	10.5	ns
				50	—	8.9	12.5	1.0	13.5	ns
			5.0±0.5	15	—	3.5	5.5	1.0	6.5	ns
				50	—	5.4	7.5	1.0	8.0	ns
Input capacitance	C _{IN}	—		—	5	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—		—	6	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

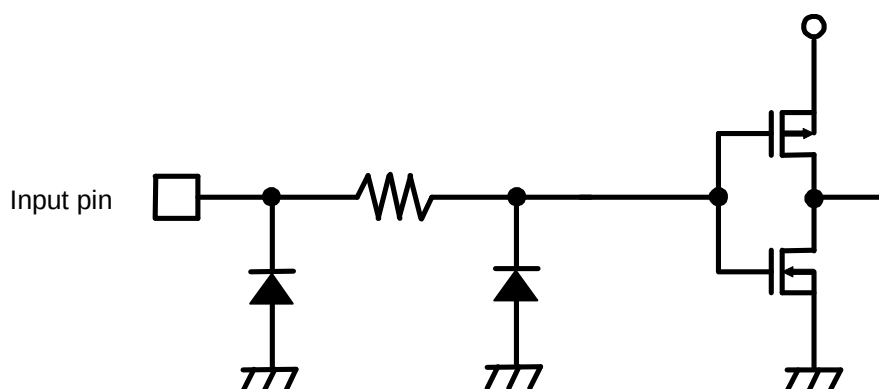
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75V08ANC is a Single 2-Input AND Gate fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve ultra high speed operation correspond to LSTTL IC's.

All gates of the internal circuitry have buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 5 V to 3 V and battery backup applications.

■ Features

- Wide power supply range: 2 V to 5.5 V
- Low current consumption: 1.0 μ A max. (at 5.5 V, 25°C)
- Typical propagation delay: $t_{PD} = 4.3$ ns (at 5 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

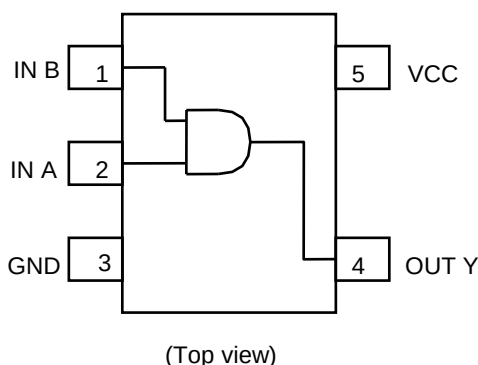
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

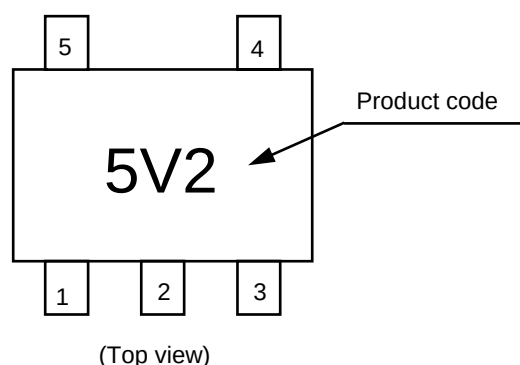
■ Package

- SC-88A

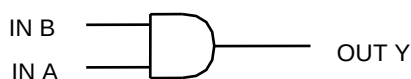
■ Pin Configuration



■ Marking Specification



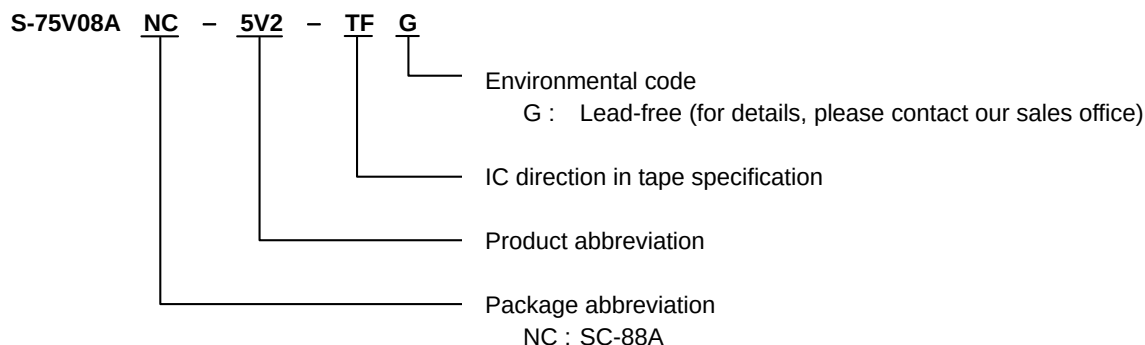
■ Logic Diagram



True values

A	B	Y
L	L	L
L	H	L
H	L	L
H	H	H

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +7.0	V
Input voltage	V_{IN}	-0.5 to +7.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±25	mA
V_{CC} /GND current	I_{CC}	±50	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

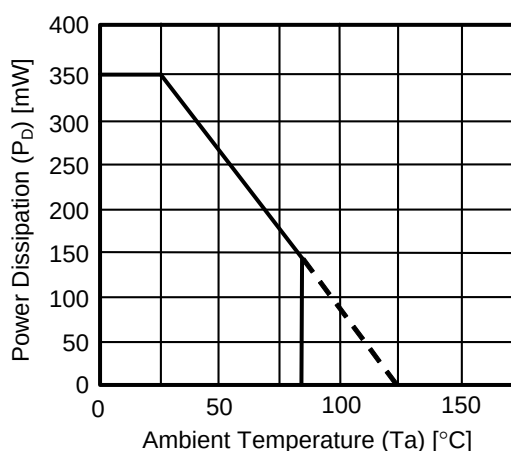
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	2 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 100 ($V_{CC} = 3.3 \pm 0.3$ V)	ns
		0 to 20 ($V_{CC} = 5 \pm 0.5$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		V _{CC}	Ta = 25°C			Ta = −40 to 85°C		Unit	
					Min.	Typ.	Max.	Min.	Max.			
Input voltage	“H” level	V _{IH}	—	2.0	1.5	—	—	1.5	—	V		
				3 to 5.5	V _{CC} ×0.7	—	—	V _{CC} ×0.7	—	V		
	“L” level	V _{IL}	—	2.0	—	—	0.5	—	0.5	V		
				3 to 5.5	—	—	V _{CC} ×0.3	—	V _{CC} ×0.3	V		
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IH}	I _{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
					4.5	4.4	4.5	—	4.4	—	V	
				I _{OH} = −4 mA	3.0	2.58	—	—	2.48	—	V	
					I _{OH} = −8 mA	4.5	3.94	—	—	3.80	—	V
	“L” level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	—	0	0.1	—	0.1	V	
					3.0	—	0	0.1	—	0.1	V	
					4.5	—	0	0.1	—	0.1	V	
				I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	V	
					I _{OL} = 8 mA	4.5	—	—	0.36	—	0.44	V
Input current		I _{IN}	V _{IN} = 5.5 V or GND	0 to 5.5	—	—	±0.1	—	±1.0	μA		
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	1.0	—	10.0	μA		

■ AC Electrical Characteristics

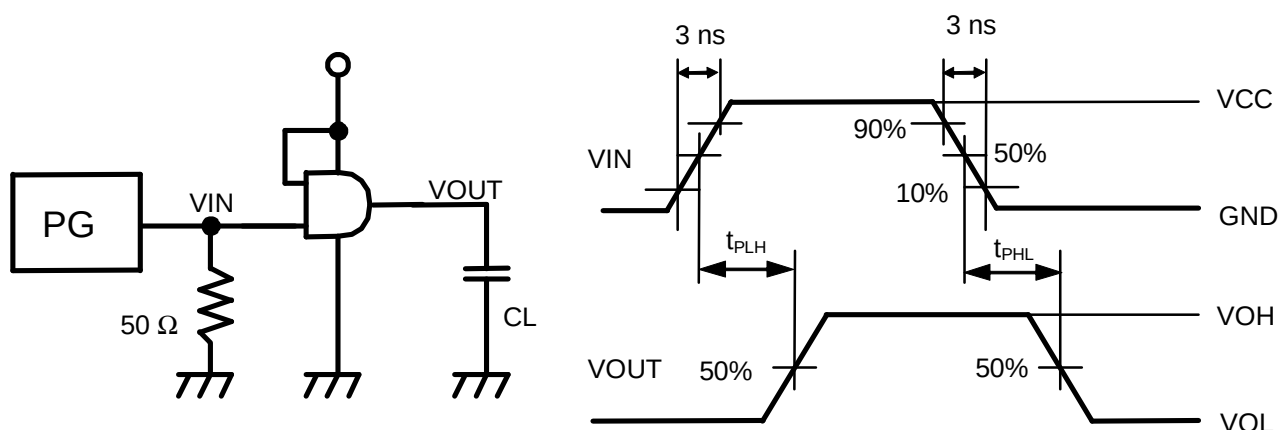
(Input $t_R = t_F = 3$ ns unless otherwise specified)

(Input $t_r = t_f = 5$ ns unless otherwise specified)										
Item	Symbol	Measurement Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit	
		V _{CC} (V)	C _L (pF)	Min.	Typ.	Max.	Min.	Max.		
Propagation delay time	t _{PLH} , t _{PHL}	—	3.3±0.3	15	—	6.2	8.8	1.0	10.5	ns
				50	—	9.6	13.5	1.0	14.5	ns
			5.0±0.5	15	—	4.3	5.9	1.0	7.0	ns
				50	—	5.7	7.9	1.0	9.0	ns
Input capacitance	C _{IN}	—		—	4	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—		—	14	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

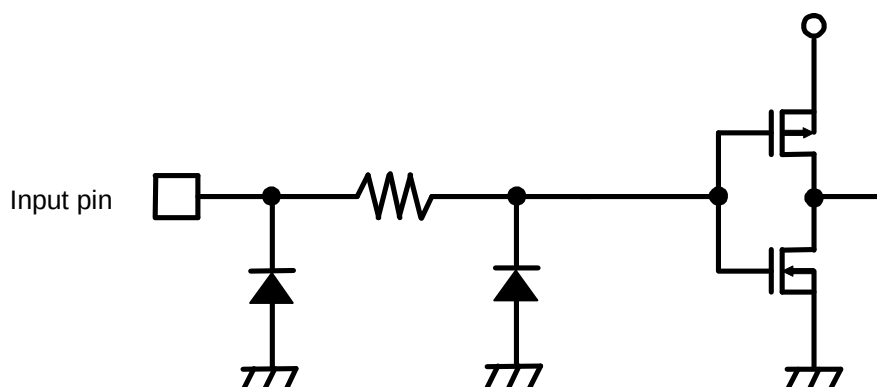
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75V14ANC is a SCHMITT INVERTER fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve ultra high speed operation correspond to LSTTL IC's.

All gates of the internal circuitry have buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 5 V to 3 V and battery backup applications.

■ Features

- Wide power supply range: 2 V to 5.5 V
- Low current consumption: 1.0 μ A max. (at 5.5 V, 25°C)
- Typical propagation delay: $t_{PD} = 5.5$ ns (at 5 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

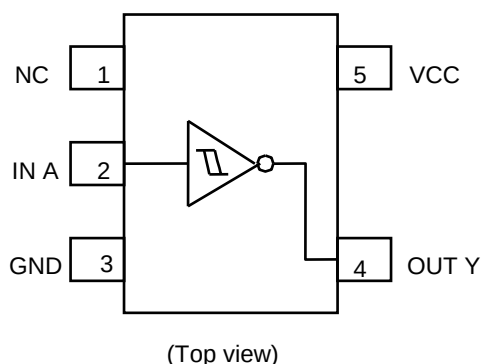
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

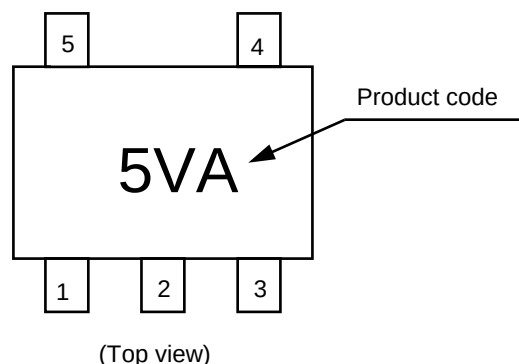
■ Package

- SC-88A

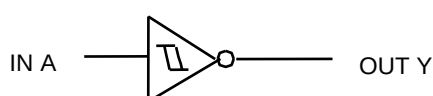
■ Pin Configuration



■ Marking Specification



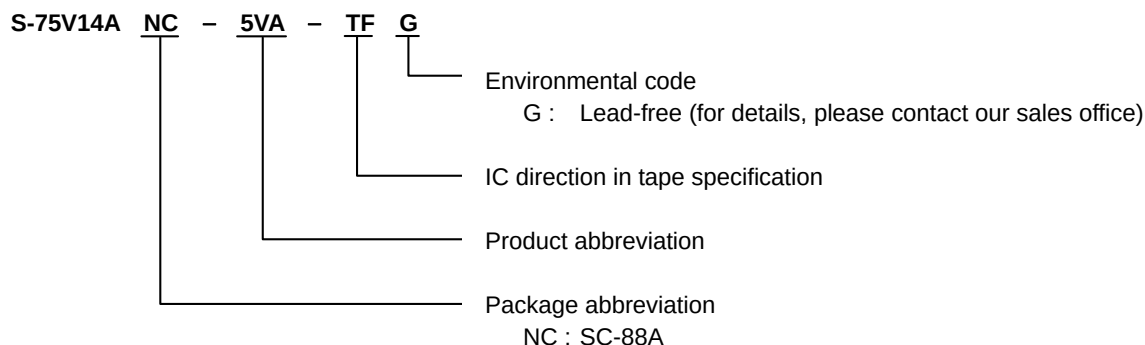
■ Logic Diagram



True values

A	Y
L	H
H	L

■ Product Name Structure



■ Absolute Maximum Ratings

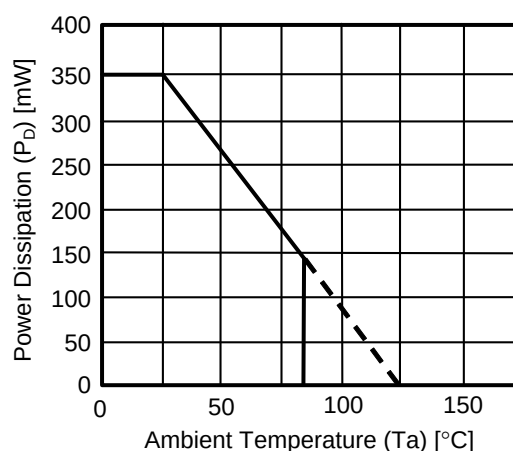
(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +7.0	V
Input voltage	V_{IN}	-0.5 to +7.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±25	mA
V_{CC} /GND current	I_{CC}	±50	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

*1. When mounted on board
[Mounted board]

- (1) Board size : 114.3 mm × 76.2 mm × 1.6 mm
(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	2 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V

■ DC Electrical Characteristics

Item		Symbol	Conditions		V _{CC}	Ta = 25°C			Ta = −40 to 85°C		Unit	
						Min.	Typ.	Max.	Min.	Max.		
Threshold voltage	“H” level	V _P	—	3.0	—	—	2.20	—	2.20	V		
				4.5	—	—	3.15	—	3.15	V		
				5.5	—	—	3.85	—	3.85	V		
	“L” level	V _N	—	3.0	0.90	—	—	0.90	—	V		
				4.5	1.35	—	—	1.35	—	V		
				5.5	1.65	—	—	1.65	—	V		
Hysteresis voltage		V _H	—	3.0	0.30	—	1.20	0.30	1.20	V		
				4.5	0.40	—	1.40	0.40	1.40	V		
				5.5	0.5	—	1.60	0.5	1.60	V		
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IL}	I _{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
					4.5	4.4	4.5	—	4.4	—	V	
				I _{OH} = −4 mA	3.0	2.58	—	—	2.48	—	V	
					I _{OH} = −8 mA	4.5	3.94	—	—	3.80	—	V
						5.5	—	—	—	—	—	V
	“L” level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA		2.0	—	0	0.1	—	0.1	V
					3.0	—	0	0.1	—	0.1	V	
					4.5	—	0	0.1	—	0.1	V	
				I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	V	
					I _{OL} = 8 mA	4.5	—	—	0.36	—	0.44	V
						5.5	—	—	—	—	—	V
Input current		I _{IN}	V _{IN} = 5.5 V or GND	0 to 5.5		—	—	±0.1	—	±1.0	μA	
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	1.0	—	10.0	μA		

■ AC Electrical Characteristics

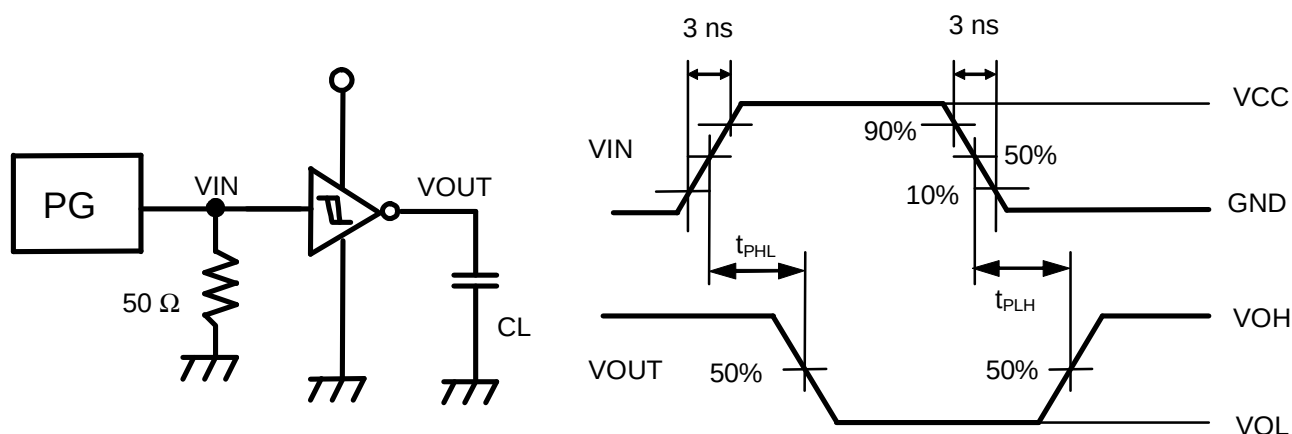
(Input $t_R = t_F = 3$ ns unless otherwise specified)

Item	Symbol	Measurement Conditions		Ta = 25°C			Ta = -40 to 85°C		Unit	
		V _{CC} (V)	C _L (pF)	Min.	Typ.	Max.	Min.	Max.		
Propagation delay time	t _{PLH} , t _{PHL}	—	3.3±0.3	15	—	8.3	12.8	1.0	15.0	ns
				50	—	10.8	16.3	1.0	18.5	ns
			5.0±0.5	15	—	5.5	8.6	1.0	10.0	ns
				50	—	7.0	10.6	1.0	12.0	ns
Input capacitance	C _{IN}	—		—	4	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—		—	14	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

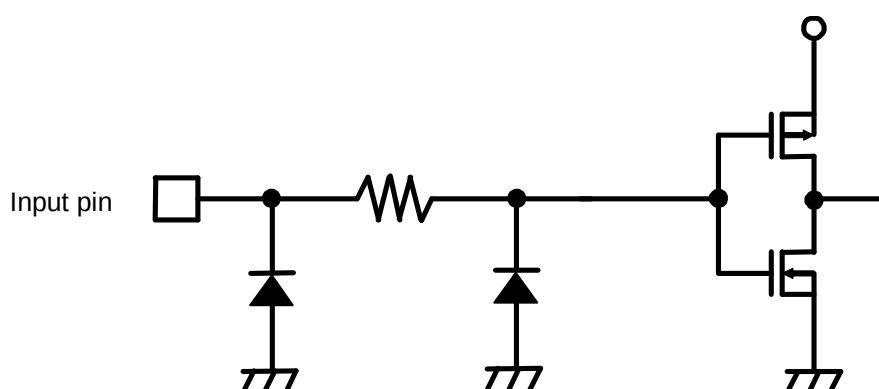
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75V32ANC is a single 2-input OR gate fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve ultra high speed operation correspond to LSTTL IC's.

All gates of the internal circuitry have buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 5 V to 3 V and battery backup applications.

■ Features

- Wide power supply range: 2 V to 5.5 V
- Low current consumption: 1.0 μ A max. (at 5.5 V, 25°C)
- Typical propagation delay: $t_{PD} = 3.8$ ns (at 5 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

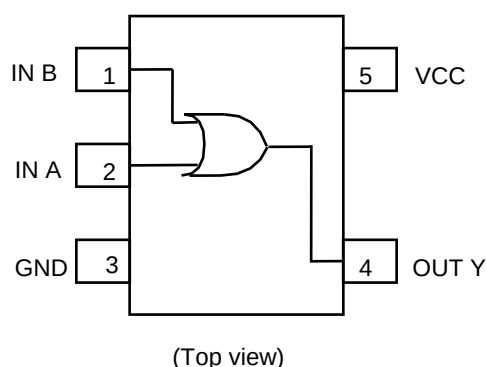
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

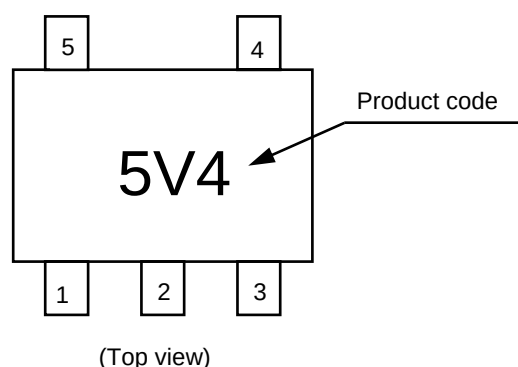
■ Package

- SC-88A

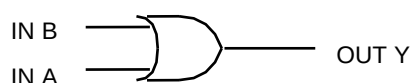
■ Pin Configuration



■ Marking Specification



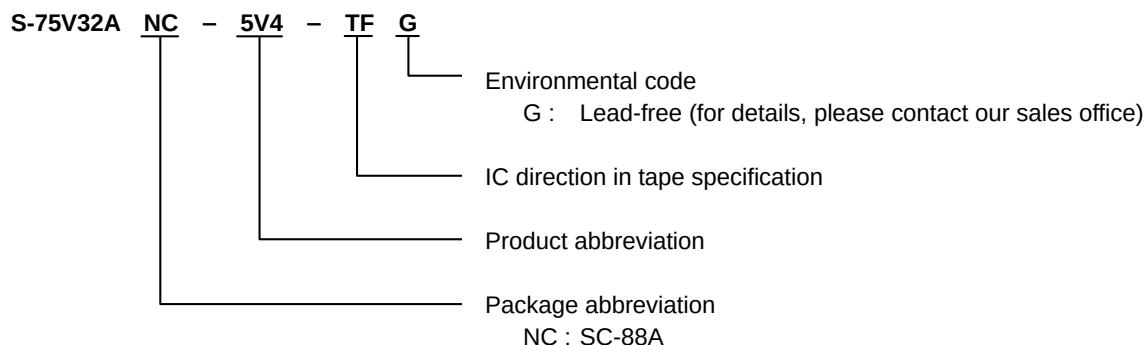
■ Logic Diagram



True values

A	B	Y
L	L	L
L	H	H
H	L	H
H	H	H

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +7.0	V
Input voltage	V_{IN}	-0.5 to +7.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±25	mA
V_{CC} /GND current	I_{CC}	±50	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

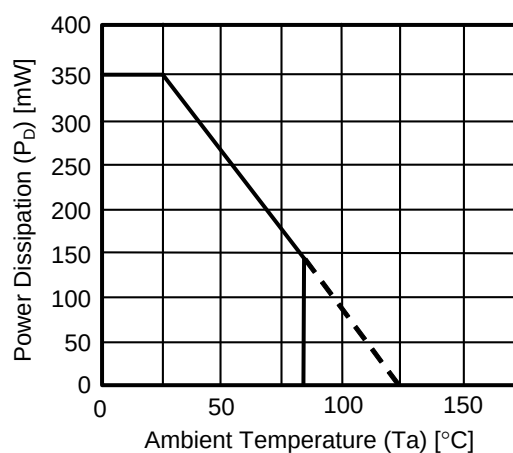
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	2 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 100 ($V_{CC} = 3.3 \pm 0.3$ V)	ns
		0 to 20 ($V_{CC} = 5 \pm 0.5$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		V _{CC}	Ta = 25°C			Ta = −40 to 85°C		Unit	
					Min.	Typ.	Max.	Min.	Max.			
Input voltage	“H” level	V _{IH}	—	2.0	1.5	—	—	1.5	—	V		
				3 to 5.5	V _{CC} ×0.7	—	—	V _{CC} ×0.7	—	V		
	“L” level	V _{IL}	—	2.0	—	—	0.5	—	0.5	V		
				3 to 5.5	—	—	V _{CC} ×0.3	—	V _{CC} ×0.3	V		
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IL} or V _{IH}	I _{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
					4.5	4.4	4.5	—	4.4	—	V	
				I _{OH} = −4 mA	3.0	2.58	—	—	2.48	—	V	
					I _{OH} = −8 mA	4.5	3.94	—	—	3.80	—	V
	“L” level	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 50 μA	2.0	—	0	0.1	—	0.1	V	
					3.0	—	0	0.1	—	0.1	V	
					4.5	—	0	0.1	—	0.1	V	
				I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	V	
					I _{OL} = 8 mA	4.5	—	—	0.36	—	0.44	V
Input current		I _{IN}	V _{IN} = 5.5 V or GND	0 to 5.5	—	—	±0.1	—	±1.0	μA		
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	1.0	—	10.0	μA		

■ AC Electrical Characteristics

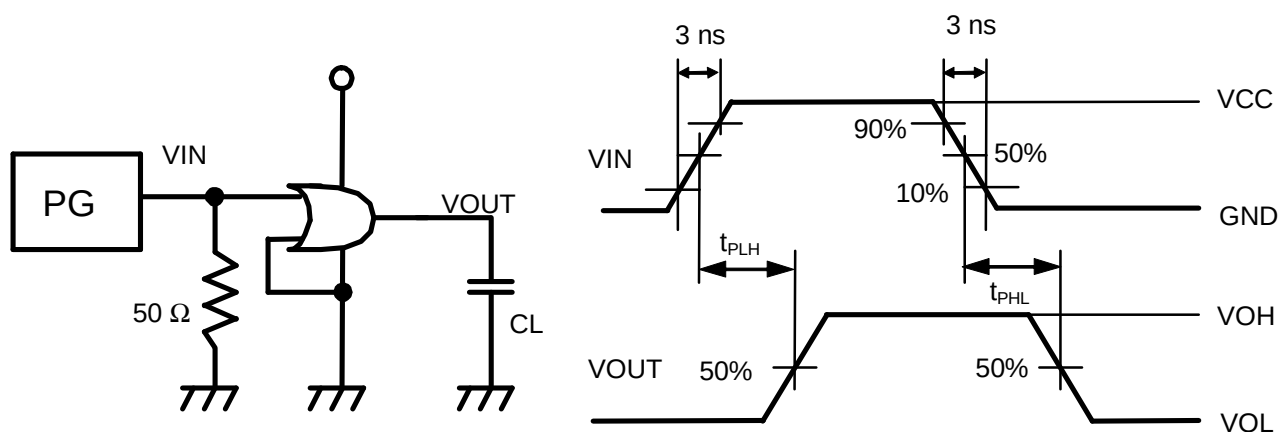
(Input $t_R = t_F = 3$ ns unless otherwise specified)

Item	Symbol	Measurement Conditions		Ta = 25°C			Ta = -40 to 85°C		Unit
		V _{CC} (V)	C _L (pF)	Min.	Typ.	Max.	Min.	Max.	
Propagation delay time	t_{PLH} , t_{PHL}	3.3±0.3	15	—	5.5	7.9	1.0	9.5	ns
			50	—	10.0	14.0	1.0	15.0	ns
		5.0±0.5	15	—	3.8	5.5	1.0	6.5	ns
			50	—	6.1	8.5	1.0	9.0	ns
Input capacitance	C _{IN}	—	—	—	4	10	—	10	pF
Equivalent internal capacitance	C _{PD} ^{*1}	—	—	—	15	—	—	—	pF

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

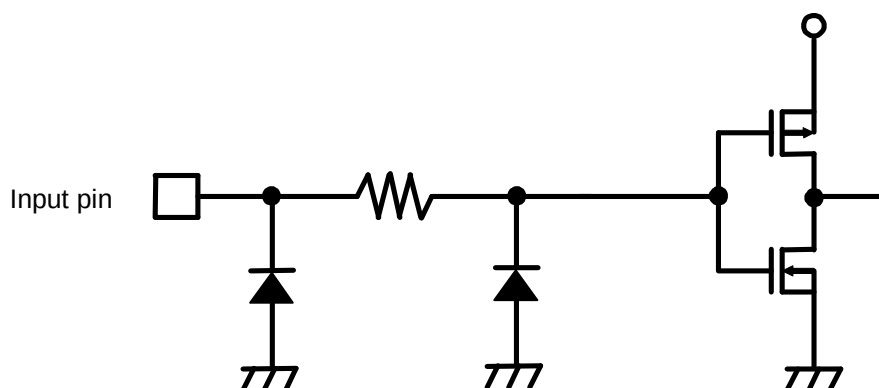
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75V86ANC is a EXCLUSIVE OR GATE fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve ultra high speed operation correspond to LSTTL IC's.

All gates of the internal circuitry have buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 5 V to 3 V and battery backup applications.

■ Features

- Wide power supply range: 2 V to 5.5 V
- Low current consumption: 1.0 μ A max. (at 5.5 V, 25°C)
- Typical propagation delay: $t_{PD} = 4.8$ ns (at 5 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

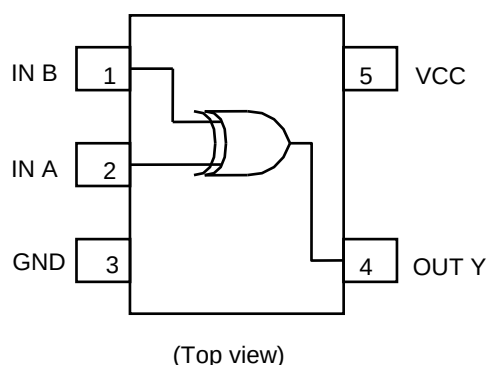
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

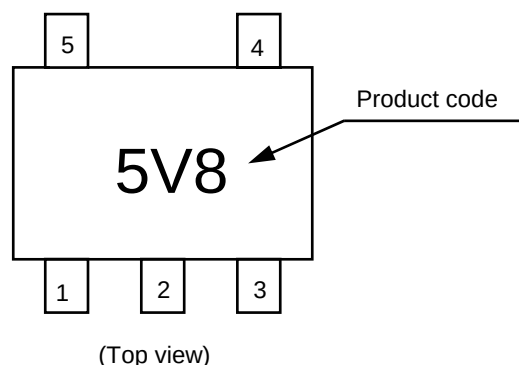
■ Package

- SC-88A

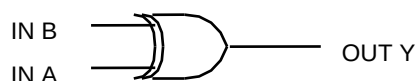
■ Pin Configuration



■ Marking Specification



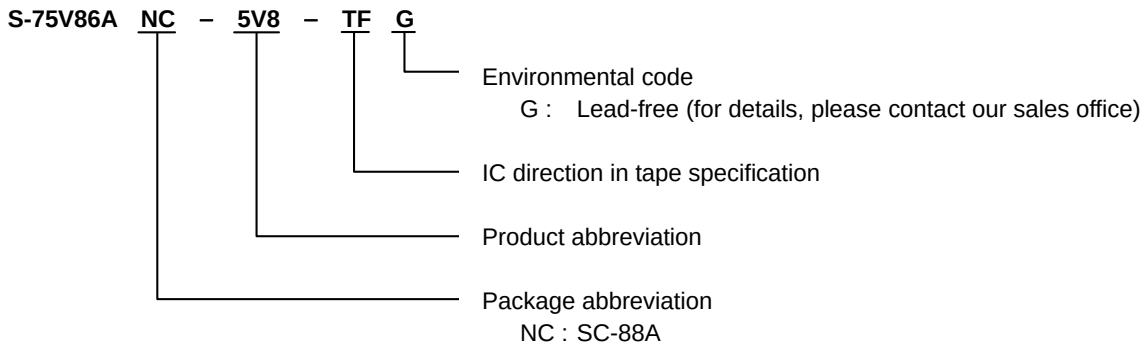
■ Logic Diagram



True values

A	B	Y
L	L	L
L	H	H
H	L	H
H	H	L

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +7.0	V
Input voltage	V_{IN}	-0.5 to +7.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±25	mA
V_{CC} /GND current	I_{CC}	±50	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

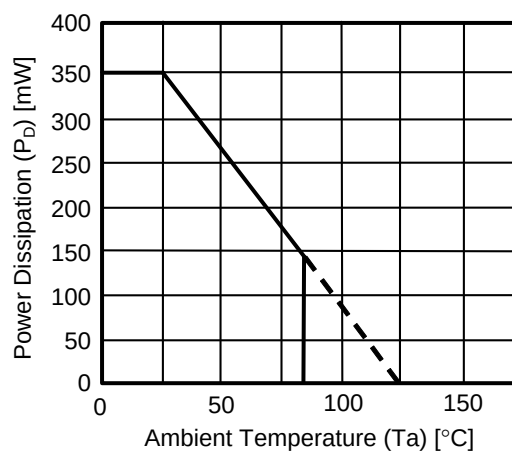
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

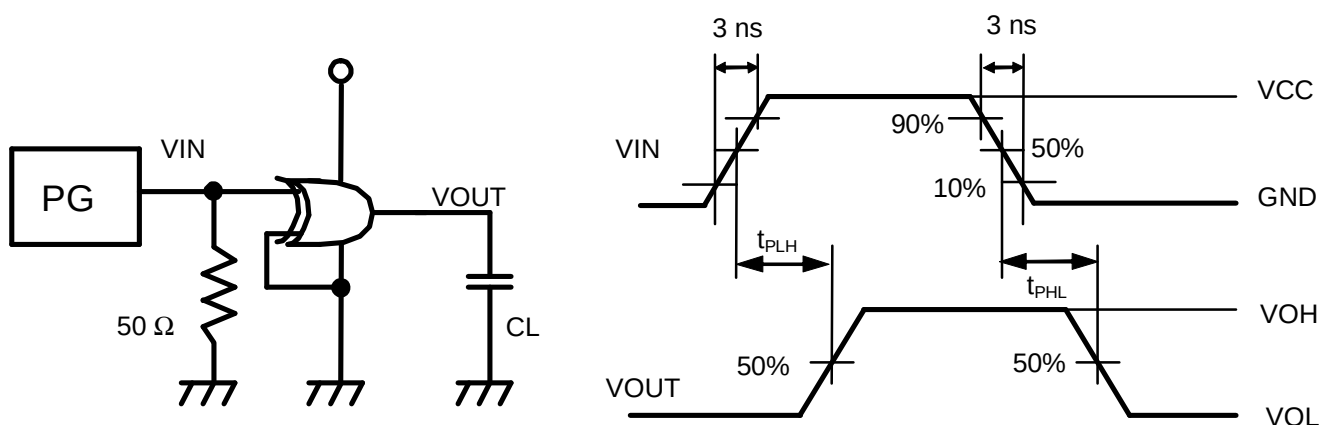
Item	Symbol	Standard	Unit
Power voltage	V_{CC}	2 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 100 ($V_{CC} = 3.3 \pm 0.3$ V)	ns
		0 to 20 ($V_{CC} = 5 \pm 0.5$ V)	ns

■ DC Electrical Characteristics

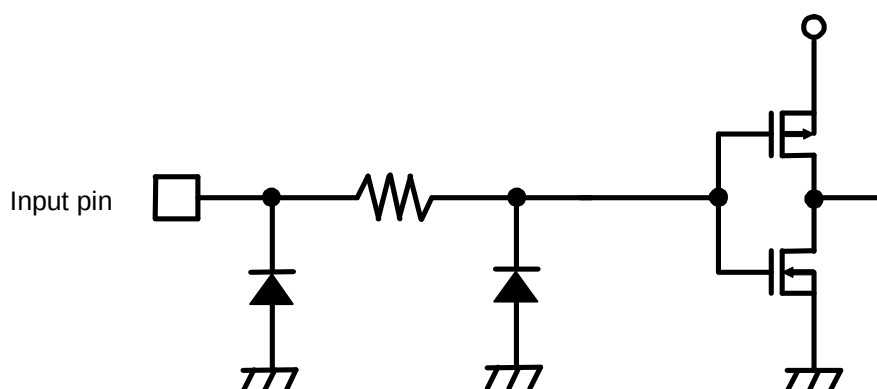
Item		Symbol	Conditions		V _{CC}	Ta = 25°C			Ta = −40 to 85°C		Unit	
					Min.	Typ.	Max.	Min.	Max.			
Input voltage	“H” level	V _{IH}	—		2.0	1.5	—	—	1.5	—	V	
				3 to 5.5	V _{CC} ×0.7	—	—	V _{CC} ×0.7	—	V		
	“L” level	V _{IL}	—		2.0	—	—	0.5	—	0.5	V	
				3 to 5.5	—	—	V _{CC} ×0.3	—	V _{CC} ×0.3	V		
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IL} or V _{IH}	I _{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
					4.5	4.4	4.5	—	4.4	—	V	
				I _{OH} = −4 mA	3.0	2.58	—	—	2.48	—	V	
					I _{OH} = −8 mA	4.5	3.94	—	—	3.80	—	V
	“L” level	V _{OL}	V _{IN} = V _{IL} or V _{IH}	I _{OL} = 50 μA	2.0	—	0	0.1	—	0.1	V	
					3.0	—	0	0.1	—	0.1	V	
					4.5	—	0	0.1	—	0.1	V	
				I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	V	
					I _{OL} = 8 mA	4.5	—	—	0.36	—	0.44	V
Input current		I _{IN}	V _{IN} = 5.5 V or GND	0 to 5.5	—	—	±0.1	—	±1.0	μA		
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	1.0	—	10.0	μA		

(Input $t_R = t_F = 3$ ns unless otherwise specified)

***1.** C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below. Current consumption is averaged by the following equation.

$$I_{CC(oper)} = C_{PD} \times V_{CC} \times fin + I_{CC}$$


■ Input Pin Equivalent Circuit



The S-75L00ANC is a single 2-input NAND gate fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve operation by only a couple of batteries (1 to 3 V). The internal circuitry has buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 3 V to 1 V and battery backup applications.

■ Features

- Wide power supply range: 1 V to 3.6 V
- Low current consumption: 1.0 μ A max. (at 3.6 V, 25°C)
- Typical propagation delay: $t_{PD} = 7$ ns (at 3 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

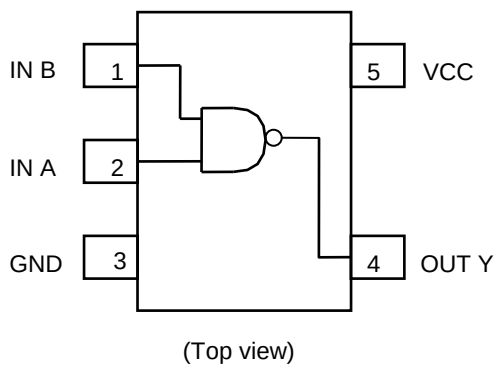
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

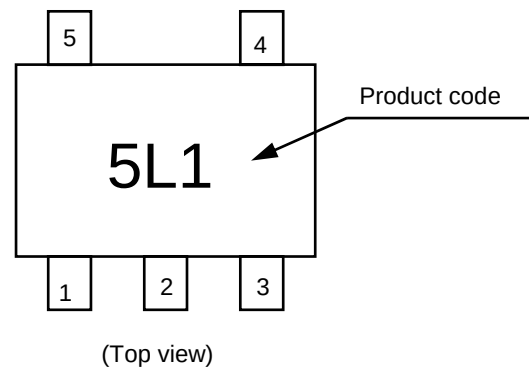
■ Package

- SC-88A

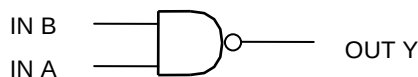
■ Pin Configuration



■ Marking Specification



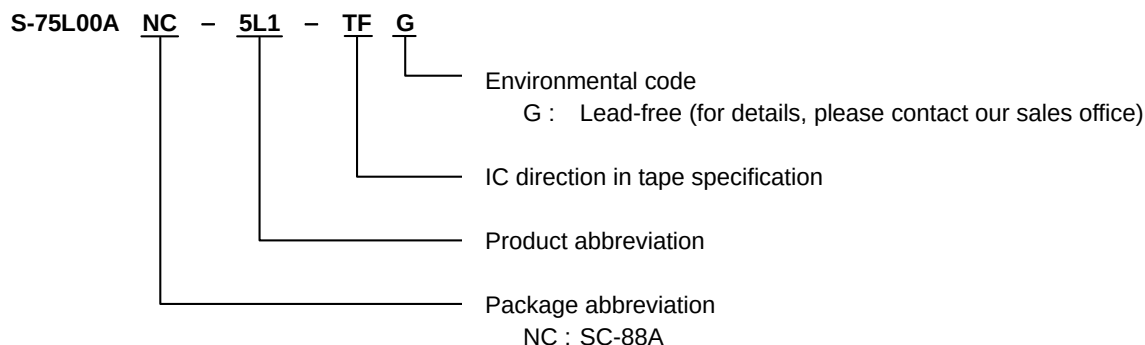
■ Logic Diagram



True values

A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +5.0	V
Input voltage	V_{IN}	-0.5 to +5.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±12.5	mA
V_{CC} /GND current	I_{CC}	±25	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

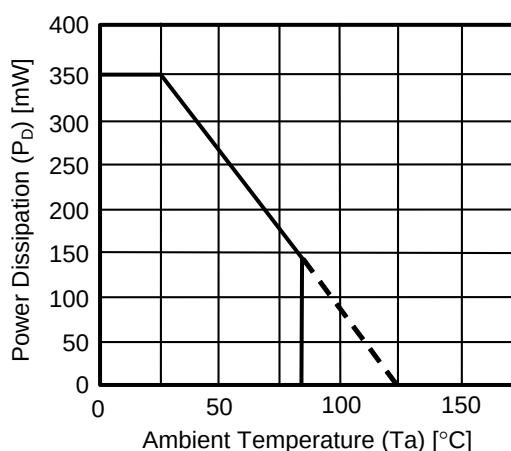
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	1 to 3.6	V
Input voltage	V_{IN}	0 to 3.6	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 1000 ($V_{CC} = 1.0$ V)	ns
		0 to 500 ($V_{CC} = 2.0$ V)	ns
		0 to 400 ($V_{CC} = 3.0$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit			
					V _{CC}	Min.	Typ.	Max.	Min.		Max.		
Input voltage	“H” level	V _{IH}	—	1.0	0.75	—	—	0.75	—	V			
				1.5	1.05	—	—	1.05	—	V			
				3.0	2.10	—	—	2.10	—	V			
	“L” level	V _{IL}	—	1.0	—	—	0.25	—	0.25	V			
				1.5	—	—	0.45	—	0.45	V			
				3.0	—	—	0.90	—	0.90	V			
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = −20 μA	1.0	0.9	1.0	—	0.9	—	V		
					1.5	1.4	1.5	—	1.4	—	V		
					3.0	2.9	3.0	—	2.9	—	V		
				I _{OH} = −1 mA	1.5	1.07	1.23	—	0.99	—	V		
					I _{OH} = −2.6 mA	3.0	2.61	2.68	—	2.55	—	V	
						“L” level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 20 μA	1.0	—	0	0.1
	1.5	—	0	0.1						—	0.1	V	
	3.0	—	0	0.1	—					0.1	V		
	I _{OL} = 1 mA	1.5	—	0.23	0.31				—	0.37	V		
		I _{OL} = 2.6 mA	3.0	—	0.23				0.31	—	0.33	V	
			Input current		I _{IN}				V _{IN} = V _{CC} or GND		3.6	—	—
	Current consumption		I _{CC}	V _{IN} = V _{CC} or GND		3.6	—	—	1.0	—	10.0	μA	

■ AC Electrical Characteristics

($C_L = 15$ pf, Input $t_R = t_F = 6$ ns, $V_{CC} = 3.3 \pm 0.3$ V, $T_a = 25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Measurement Conditions	Min.	Typ.	Max.	Unit
Output rise / fall time	t_{TLH} , t_{THL}	—	—	4.0	8.5	ns
Propagation delay time	t_{PLH} , t_{PHL}	—	—	6.0	9.0	ns

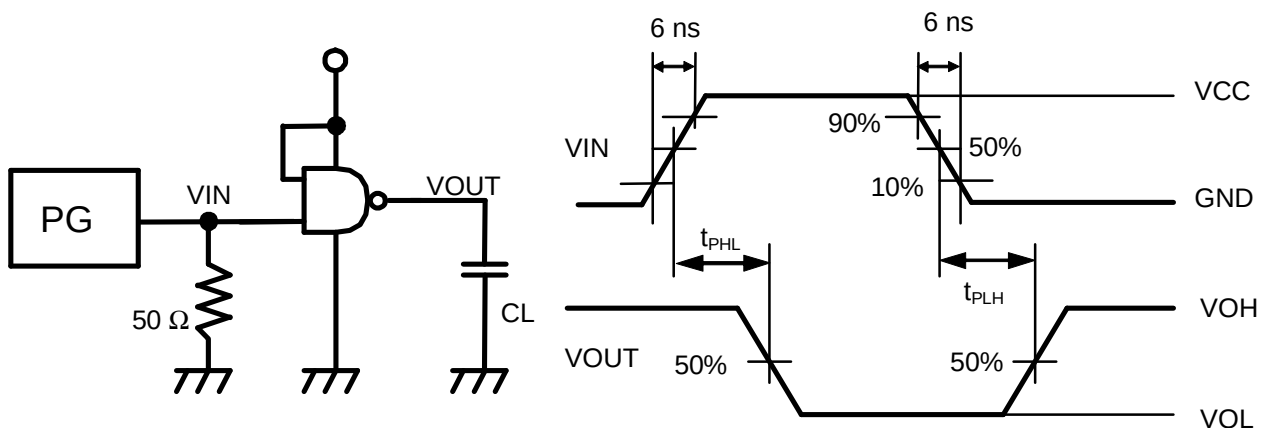
($C_L = 25$ pf, Input $t_R = t_F = 6$ ns unless otherwise specified)

Item	Symbol	Measurement Conditions	Ta = 25°C			Ta = −40 to 85°C		Unit	
			V _{CC} (V)	Min.	Typ.	Max.	Min.		Max.
Output rise / fall time	t _{TLH} , t _{THL}	—	1.0	—	35	70	—	90	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Propagation delay time	t _{PLH} , t _{PHL}	—	1.0	—	30	60	—	75	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Input capacitance	C _{IN}	—	—	5	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—	—	10	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

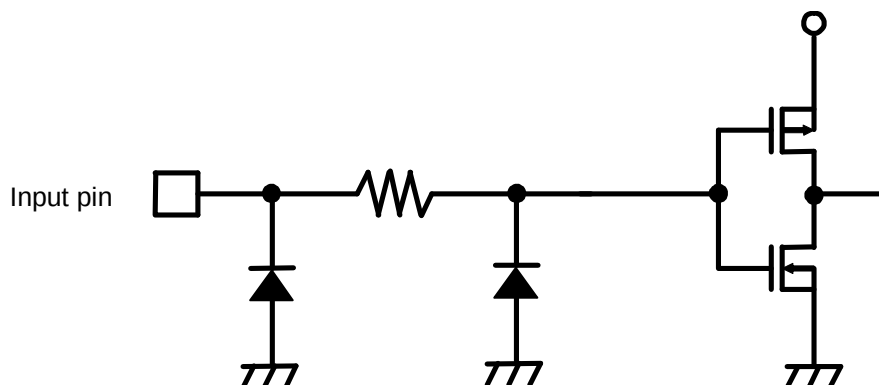
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75L02ANC is a single 2-input NOR gate fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve operation by only a couple of batteries (1 to 3 V). The internal circuitry has buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 3 V to 1 V and battery backup applications.

■ Features

- Wide power supply range: 1 V to 3.6 V
- Low current consumption: 1.0 μ A max. (at 3.6 V, 25°C)
- Typical propagation delay: $t_{PD} = 7$ ns (at 3 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

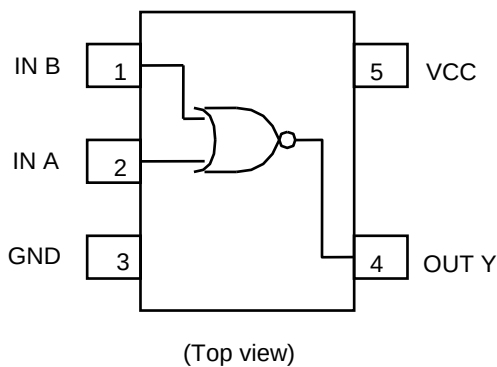
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

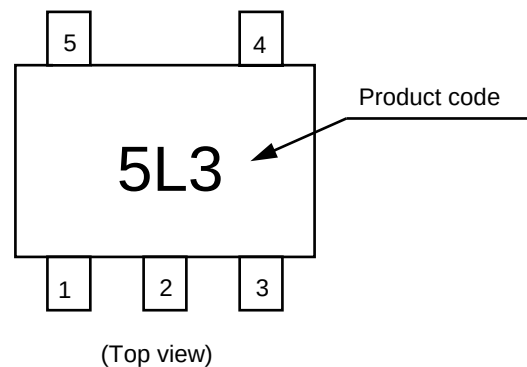
■ Package

- SC-88A

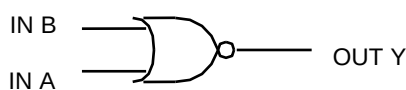
■ Pin Configuration



■ Marking Specification



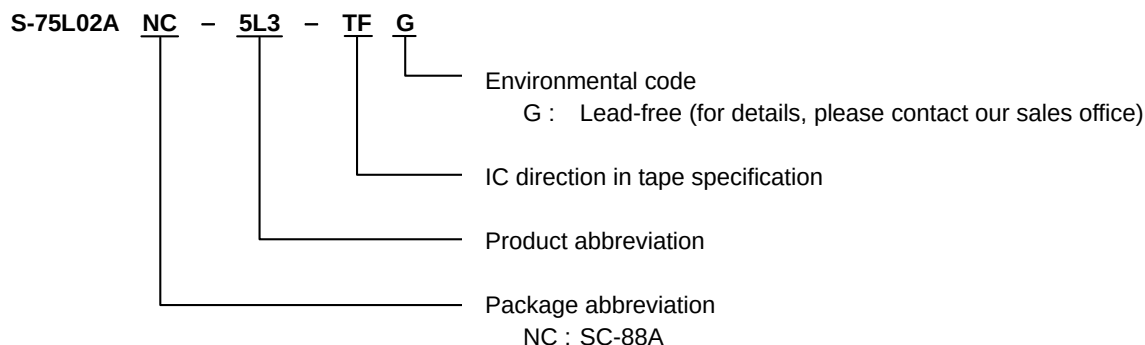
■ Logic Diagram



True values

A	B	Y
L	L	H
L	H	L
H	L	L
H	H	L

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +5.0	V
Input voltage	V_{IN}	-0.5 to +5.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±12.5	mA
V_{CC} /GND current	I_{CC}	±25	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

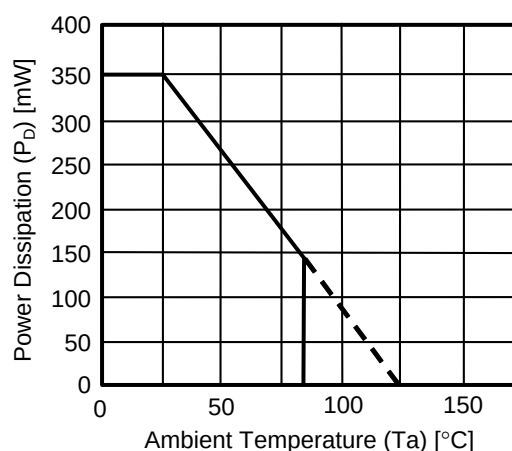
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	1 to 3.6	V
Input voltage	V_{IN}	0 to 3.6	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 1000 ($V_{CC} = 1.0$ V)	ns
		0 to 500 ($V_{CC} = 2.0$ V)	ns
		0 to 400 ($V_{CC} = 3.0$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		V _{CC}	Ta = 25°C			Ta = −40 to 85°C		Unit	
						Min.	Typ.	Max.	Min.	Max.		
Input voltage	“H” level	V _{IH}	—		1.0	0.75	—	—	0.75	—	V	
					1.5	1.05	—	—	1.05	—	V	
					3.0	2.10	—	—	2.10	—	V	
	“L” level	V _{IL}	—		1.0	—	—	0.25	—	0.25	V	
					1.5	—	—	0.45	—	0.45	V	
					3.0	—	—	0.90	—	0.90	V	
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IL}	I _{OH} = −20 μA	1.0	0.9	1.0	—	0.9	—	V	
					1.5	1.4	1.5	—	1.4	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
					I _{OH} = −1 mA	1.5	1.07	1.23	—	0.99	—	V
					I _{OH} = −2.6 mA	3.0	2.61	2.68	—	2.55	—	V
	“L” level	V _{OL}	V _{IN} = V _{IL} or V _{IH}	I _{OL} = 20 μA	1.0	—	0	0.1	—	0.1	V	
					1.5	—	0	0.1	—	0.1	V	
					3.0	—	0	0.1	—	0.1	V	
					I _{OL} = 1 mA	1.5	—	0.23	0.31	—	0.37	V
					I _{OL} = 2.6 mA	3.0	—	0.23	0.31	—	0.33	V
Input current		I _{IN}	V _{IN} = V _{CC} or GND		3.6	—	—	±0.1	—	±1.0	μA	
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND		3.6	—	—	1.0	—	10.0	μA	

■ AC Electrical Characteristics

($C_L = 15$ pf, Input $t_R = t_F = 6$ ns, $V_{CC} = 3.3 \pm 0.3$ V, $T_a = 25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Measurement Conditions	Min.	Typ.	Max.	Unit
Output rise / fall time	t_{TLH} , t_{THL}	—	—	4.0	8.0	ns
Propagation delay time	t_{PLH} , t_{PHL}	—	—	6.0	9.0	ns

($C_L = 25$ pf, Input $t_R = t_F = 6$ ns unless otherwise specified)

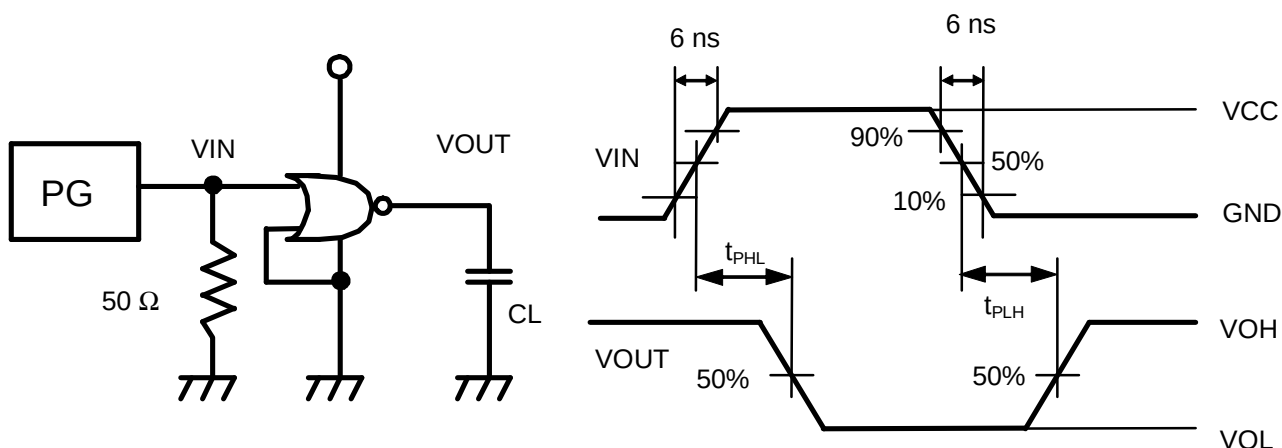
Item	Symbol	Measurement Conditions	Ta = 25°C			Ta = −40 to 85°C		Unit	
			VCC (V)	Min.	Typ.	Max.	Min.		Max.
Output rise / fall time	tTLH, tTHL	—	1.0	—	35	70	—	90	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Propagation delay time	tPLH, tPHL	—	1.0	—	30	60	—	75	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Input capacitance	CIN	—	—	5	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—	—	10	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.

Current consumption is averaged by the following equation.

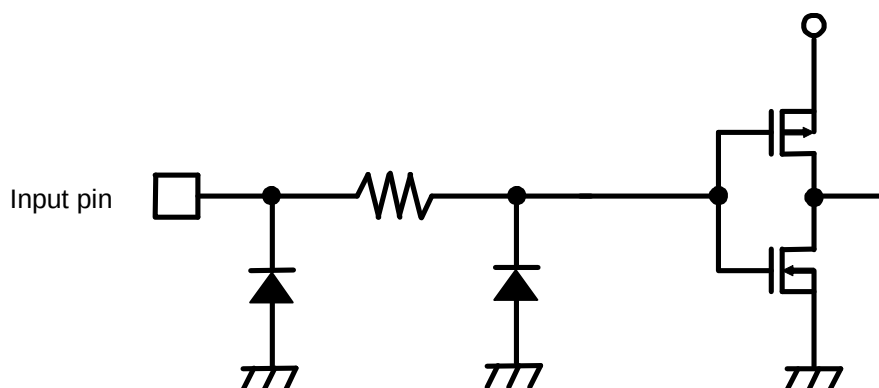
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times fin + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75L04ANC is an inverter fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve operation by only a couple of batteries (1 to 3 V).

The internal circuitry has buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 3 V to 1 V and battery backup applications.

■ Features

- Wide power supply range: 1 V to 3.6 V
- Low current consumption: 1.0 μ A max. (at 3.6 V, 25°C)
- Typical propagation delay: $t_{PD} = 7$ ns (at 3 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

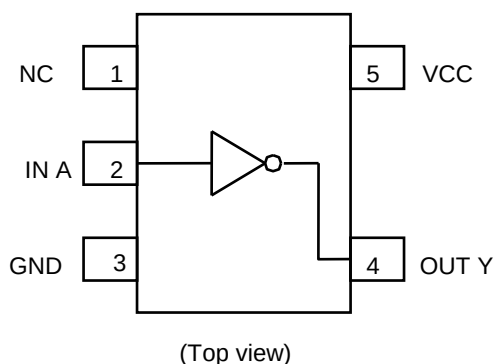
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

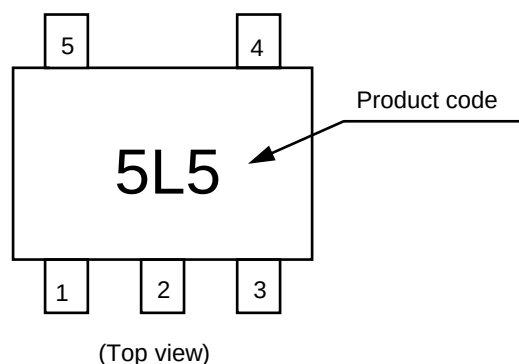
■ Package

- SC-88A

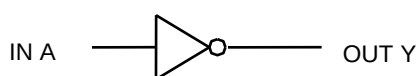
■ Pin Configuration



■ Marking Specification

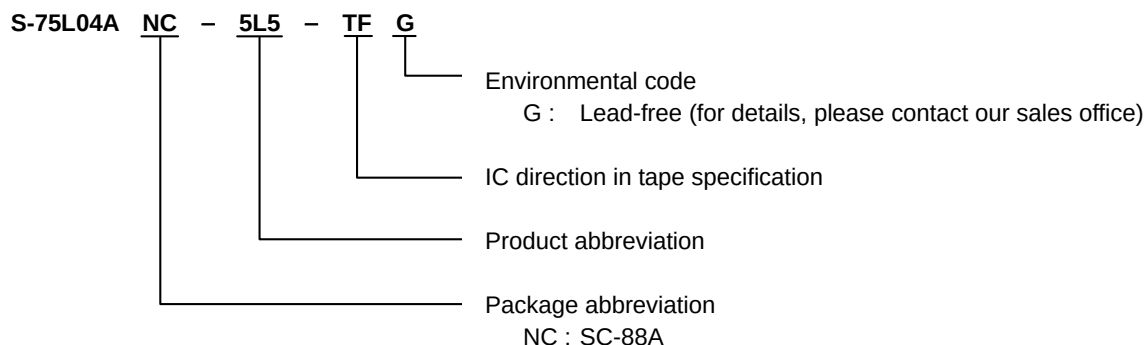


■ Logic Diagram



True values	
A	Y
L	H
H	L

■ Product Name Structure



■ Absolute Maximum Ratings

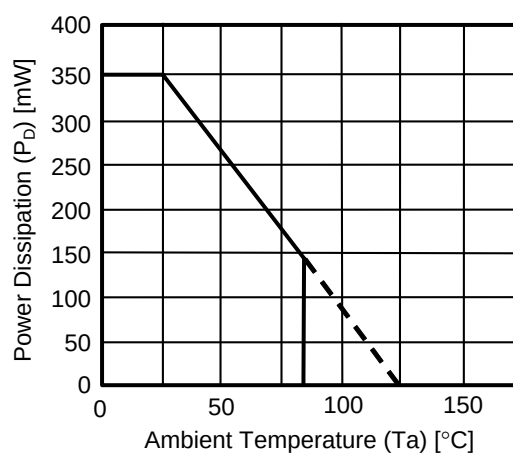
(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +5.0	V
Input voltage	V_{IN}	-0.5 to +5.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±12.5	mA
V_{CC} /GND current	I_{CC}	±25	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

*1. When mounted on board
[Mounted board]

- (1) Board size : 114.3 mm × 76.2 mm × 1.6 mm
- (2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	1 to 3.6	V
Input voltage	V_{IN}	0 to 3.6	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 1000 ($V_{CC} = 1.0$ V)	ns
		0 to 500 ($V_{CC} = 2.0$ V)	ns
		0 to 400 ($V_{CC} = 3.0$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit		
					V _{CC}	Min.	Typ.	Max.	Min.		Max.	
Input voltage	“H” level	V _{IH}	—	1.0	0.75	—	—	0.75	—	V		
				1.5	1.05	—	—	1.05	—	V		
				3.0	2.10	—	—	2.10	—	V		
	“L” level	V _{IL}	—	1.0	—	—	0.25	—	0.25	V		
				1.5	—	—	0.45	—	0.45	V		
				3.0	—	—	0.90	—	0.90	V		
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IL}	I _{OH} = −20 μA	1.0	0.9	1.0	—	0.9	—	V	
					1.5	1.4	1.5	—	1.4	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
				I _{OH} = −1 mA	1.5	1.07	1.23	—	0.99	—	V	
					I _{OH} = −2.6 mA	3.0	2.61	2.68	—	2.55	—	V
	“L” level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 20 μA	1.0	—	0	0.1	—	0.1	V	
					1.5	—	0	0.1	—	0.1	V	
					3.0	—	0	0.1	—	0.1	V	
				I _{OL} = 1 mA	1.5	—	0.23	0.31	—	0.37	V	
					I _{OL} = 2.6 mA	3.0	—	0.23	0.31	—	0.33	V
Input current		I _{IN}	V _{IN} = V _{CC} or GND	3.6	—	—	±0.1	—	±1.0	μA		
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	3.6	—	—	1.0	—	10.0	μA		

■ AC Electrical Characteristics

($C_L = 15$ pf, Input $t_R = t_F = 6$ ns, $V_{CC} = 3.3 \pm 0.3$ V, $T_a = 25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Measurement Conditions	Min.	Typ.	Max.	Unit
Output rise / fall time	t_{TLH} , t_{THL}	—	—	4.0	8.0	ns
Propagation delay time	t_{PLH} , t_{PHL}	—	—	6.0	9.0	ns

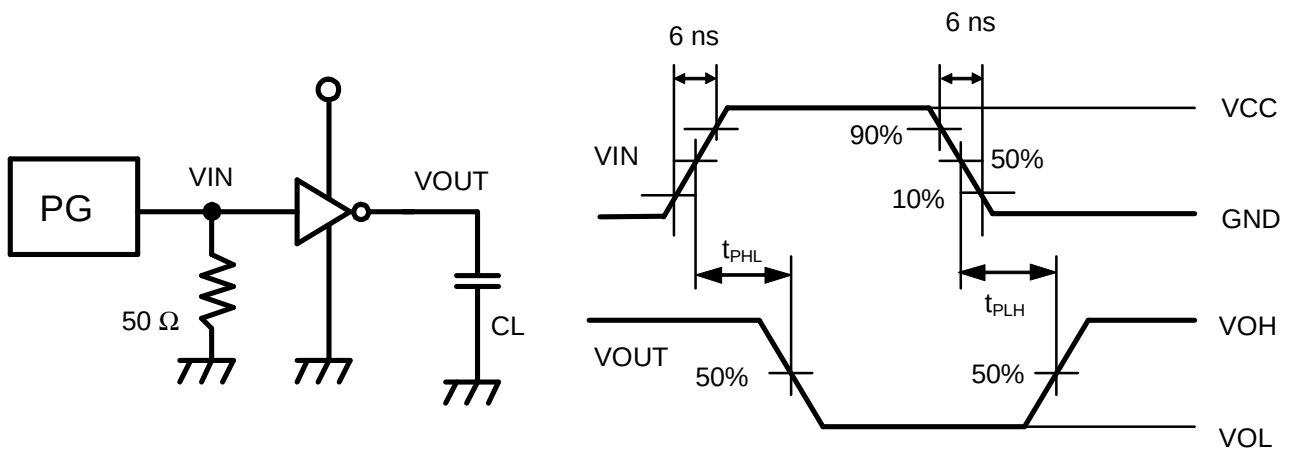
($C_L = 25$ pf, Input $t_R = t_F = 6$ ns unless otherwise specified)

Item	Symbol	Measurement Conditions	Ta = 25°C			Ta = −40 to 85°C		Unit	
			V _{CC} (V)	Min.	Typ.	Max.	Min.		Max.
Output rise / fall time	t _{TLH} , t _{THL}	—	1.0	—	35	70	—	90	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Propagation delay time	t _{PLH} , t _{PHL}	—	1.0	—	30	60	—	75	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Input capacitance	C _{IN}	—	—	5	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—	—	10	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

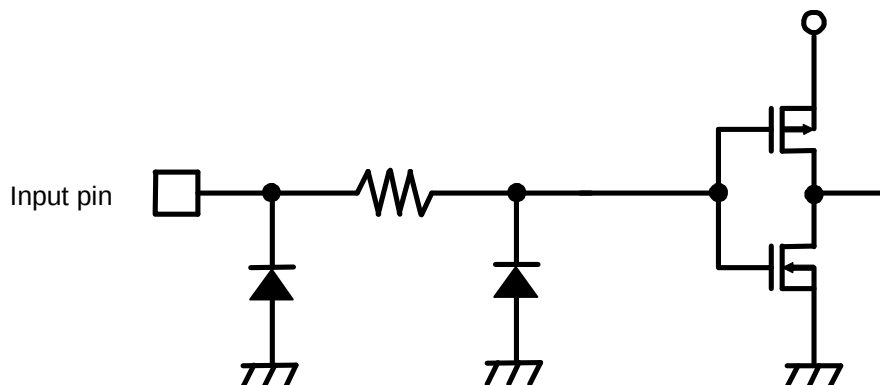
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times fin + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75LU04ANC is a single packaged inverter without buffer fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve operation by only a couple of batteries (1 to 3 V).

The S-75LU04ANC is suitable for a wide variety of linear circuits.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 3 V to 1 V and battery backup applications.

■ Features

- Wide power supply range: 1 V to 3.6 V
- Low current consumption: 1.0 μ A max. (at 3.6 V, 25°C)
- Typical propagation delay: $t_{PD} = 6$ ns (at 3 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 10\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

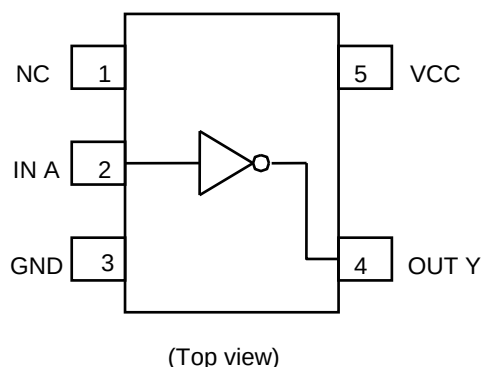
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

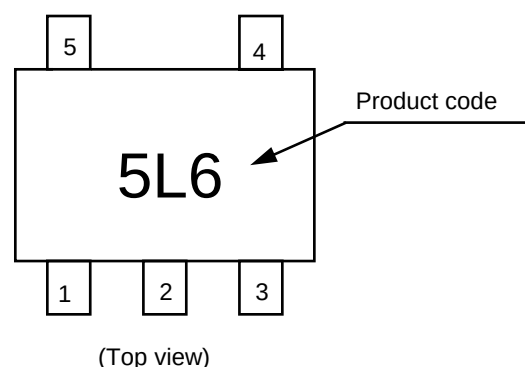
■ Package

- SC-88A

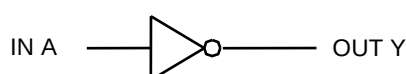
■ Pin Configuration



■ Marking Specification



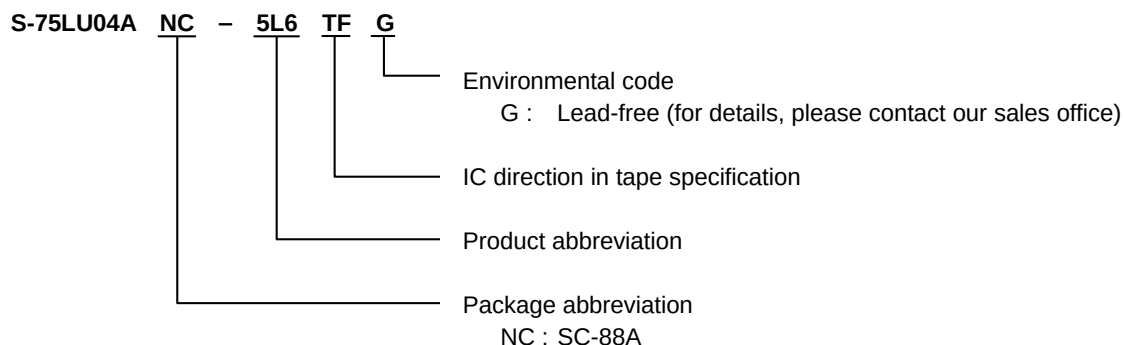
■ Logic Diagram



True values

A	Y
L	H
H	L

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +5.0	V
Input voltage	V_{IN}	-0.5 to +5.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±12.5	mA
V_{CC} /GND current	I_{CC}	±25	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

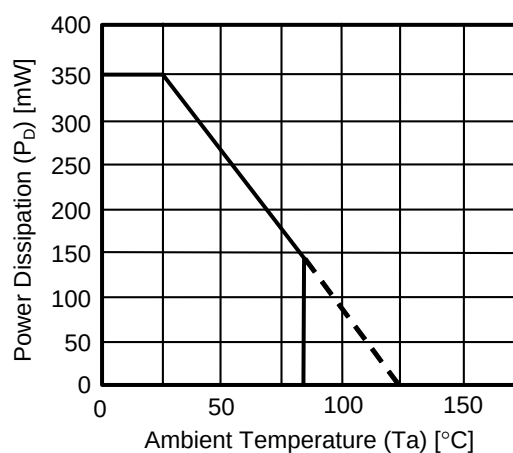
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	1 to 3.6	V
Input voltage	V_{IN}	0 to 3.6	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 1000 ($V_{CC} = 1.0$ V)	ns
		0 to 500 ($V_{CC} = 2.0$ V)	ns
		0 to 400 ($V_{CC} = 3.0$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit		
					V _{CC}	Min.	Typ.	Max.	Min.		Max.	
Input voltage	“H” level	V _{IH}	—	1.0	0.75	—	—	0.75	—	V		
				1.5	1.05	—	—	1.05	—	V		
				3.0	2.10	—	—	2.10	—	V		
	“L” level	V _{IL}	—	1.0	—	—	0.25	—	0.25	V		
				1.5	—	—	0.45	—	0.45	V		
				3.0	—	—	0.90	—	0.90	V		
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IL}	I _{OH} = −20 μA	1.0	0.9	1.0	—	0.9	—	V	
					1.5	1.4	1.5	—	1.4	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
				I _{OH} = −1 mA	1.5	1.07	1.23	—	0.99	—	V	
					I _{OH} = −2.6 mA	3.0	2.61	2.68	—	2.55	—	V
	“L” level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 20 μA	1.0	—	0	0.1	—	0.1	V	
					1.5	—	0	0.1	—	0.1	V	
					3.0	—	0	0.1	—	0.1	V	
				I _{OL} = 1 mA	1.5	—	0.23	0.31	—	0.37	V	
					I _{OL} = 2.6 mA	3.0	—	0.23	0.31	—	0.33	V
Input current		I _{IN}	V _{IN} = V _{CC} or GND	3.6	—	—	±0.1	—	±1.0	μA		
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	3.6	—	—	1.0	—	10.0	μA		

■ AC Electrical Characteristics

($C_L = 15$ pf, Input $t_R = t_F = 6$ ns, $V_{CC} = 3.3 \pm 0.3$ V, $T_a = 25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Measurement Conditions	Min.	Typ.	Max.	Unit
Output rise / fall time	t_{TLH} , t_{THL}	—	—	6.0	9.0	ns
Propagation delay time	t_{PLH} , t_{PHL}	—	—	4.0	10.0	ns

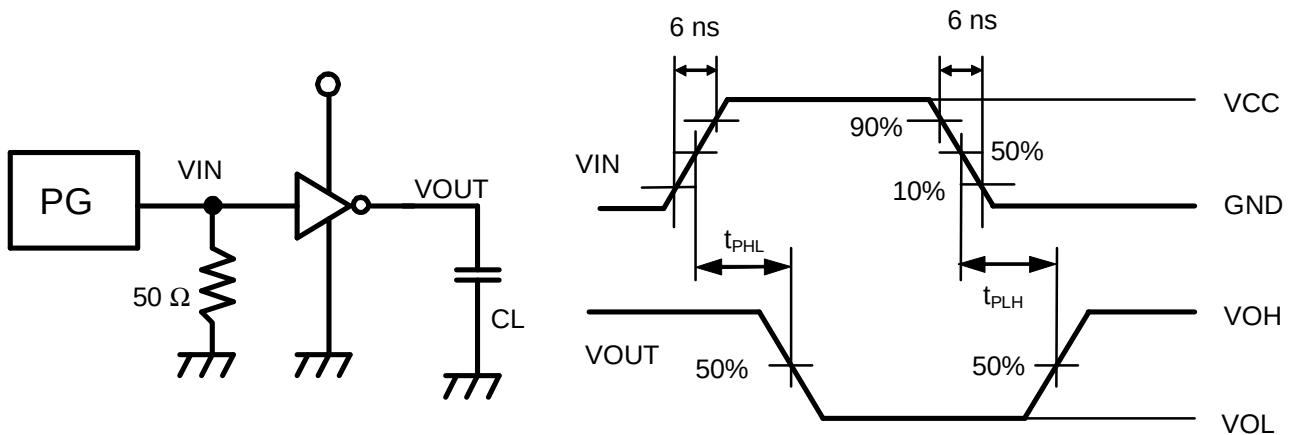
($C_L = 25$ pf, Input $t_R = t_F = 6$ ns unless otherwise specified)

Item	Symbol	Measurement Conditions	Ta = 25°C			Ta = −40 to 85°C		Unit	
			V _{CC} (V)	Min.	Typ.	Max.	Min.		Max.
Output rise / fall time	t _{TLH} , t _{THL}	—	1.0	—	35	70	—	90	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Propagation delay time	t _{PLH} , t _{PHL}	—	1.0	—	20	40	—	50	ns
			1.5	—	10	15	—	20	ns
			3.0	—	6	9	—	12	ns
Input capacitance	C _{IN}	—	—	5	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—	—	10	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

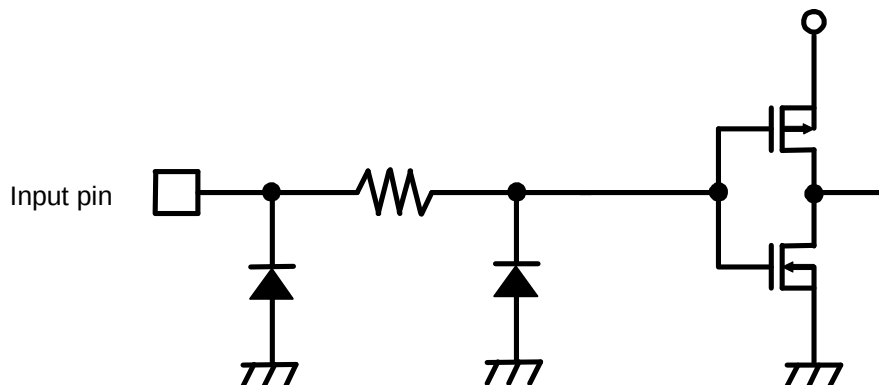
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75L08ANC is a single 2-Input AND Gate fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve operation by only a couple of batteries (1 to 3 V). The internal circuitry has buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 3 V to 1 V and battery backup applications.

■ Features

- Wide power supply range: 1 V to 3.6 V
- Low current consumption: 1.0 μ A max. (at 3.6 V, 25°C)
- Typical propagation delay: $t_{PD} = 7$ ns (at 3 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

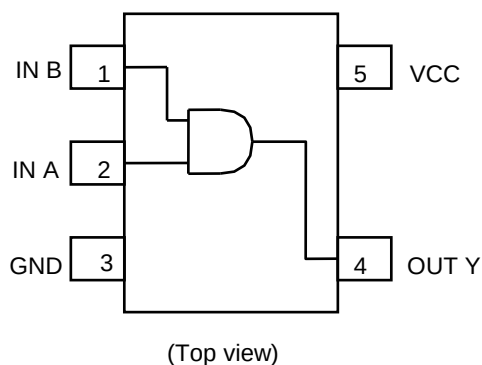
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

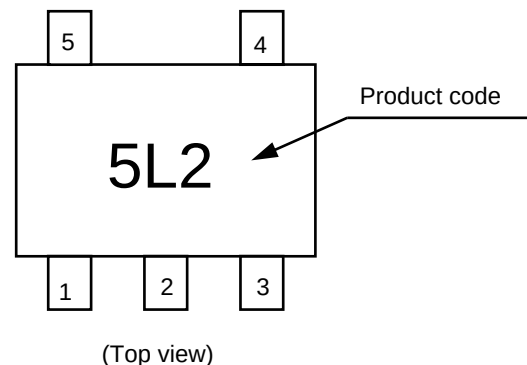
■ Package

- SC-88A

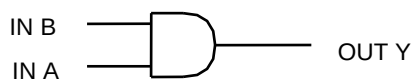
■ Pin Configuration



■ Marking Specification



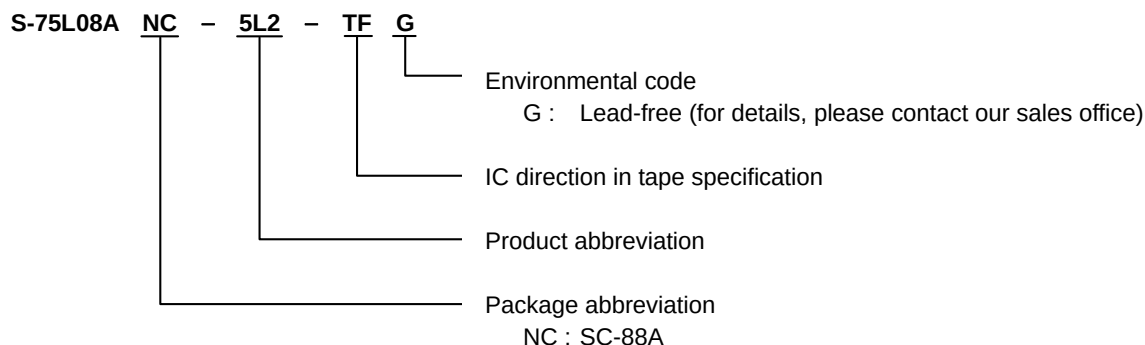
■ Logic Diagram



True values

A	B	Y
L	L	L
L	H	L
H	L	L
H	H	H

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +5.0	V
Input voltage	V_{IN}	-0.5 to +5.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±12.5	mA
V_{CC}/GND current	I_{CC}	±25	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

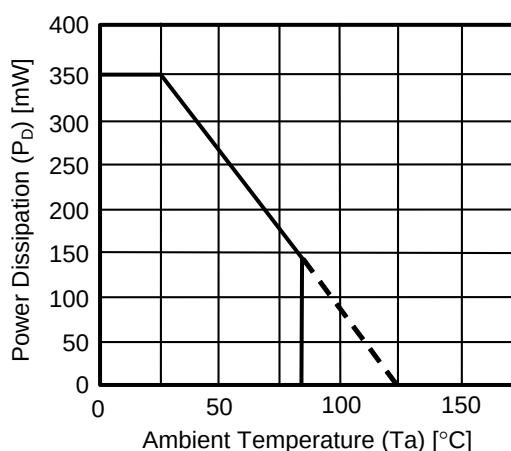
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	1 to 3.6	V
Input voltage	V_{IN}	0 to 3.6	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 1000 ($V_{CC} = 1.0$ V)	ns
		0 to 500 ($V_{CC} = 2.0$ V)	ns
		0 to 400 ($V_{CC} = 3.0$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit		
					V _{CC}	Min.	Typ.	Max.	Min.		Max.	
Input voltage	“H” level	V _{IH}	—	1.0	0.75	—	—	0.75	—	V		
				1.5	1.05	—	—	1.05	—	V		
				3.0	2.10	—	—	2.10	—	V		
	“L” level	V _{IL}	—	1.0	—	—	0.25	—	0.25	V		
				1.5	—	—	0.45	—	0.45	V		
				3.0	—	—	0.90	—	0.90	V		
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IH}	I _{OH} = −20 μA	1.0	0.9	1.0	—	0.9	—	V	
					1.5	1.4	1.5	—	1.4	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
				I _{OH} = −1 mA	1.5	1.07	1.23	—	0.99	—	V	
					I _{OH} = −2.6 mA	3.0	2.61	2.68	—	2.55	—	V
	“L” level	V _{OL}	V _{IN} = V _{IL} or V _{IH}	I _{OL} = 20 μA	1.0	—	0	0.1	—	0.1	V	
					1.5	—	0	0.1	—	0.1	V	
					3.0	—	0	0.1	—	0.1	V	
				I _{OL} = 1 mA	1.5	—	0.23	0.31	—	0.37	V	
					I _{OL} = 2.6 mA	3.0	—	0.23	0.31	—	0.33	V
Input current		I _{IN}	V _{IN} = V _{CC} or GND	3.6	—	—	±0.1	—	±1.0	μA		
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	3.6	—	—	1.0	—	10.0	μA		

■ AC Electrical Characteristics

($C_L = 15$ pf, Input $t_R = t_F = 6$ ns, $V_{CC} = 3.3 \pm 0.3$ V, $T_a = 25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Measurement Conditions	Min.	Typ.	Max.	Unit
Output rise / fall time	t_{TLH} , t_{THL}	—	—	4.0	8.0	ns
Propagation delay time	t_{PLH} , t_{PHL}	—	—	6.0	9.0	ns

($C_L = 25$ pf, Input $t_R = t_F = 6$ ns unless otherwise specified)

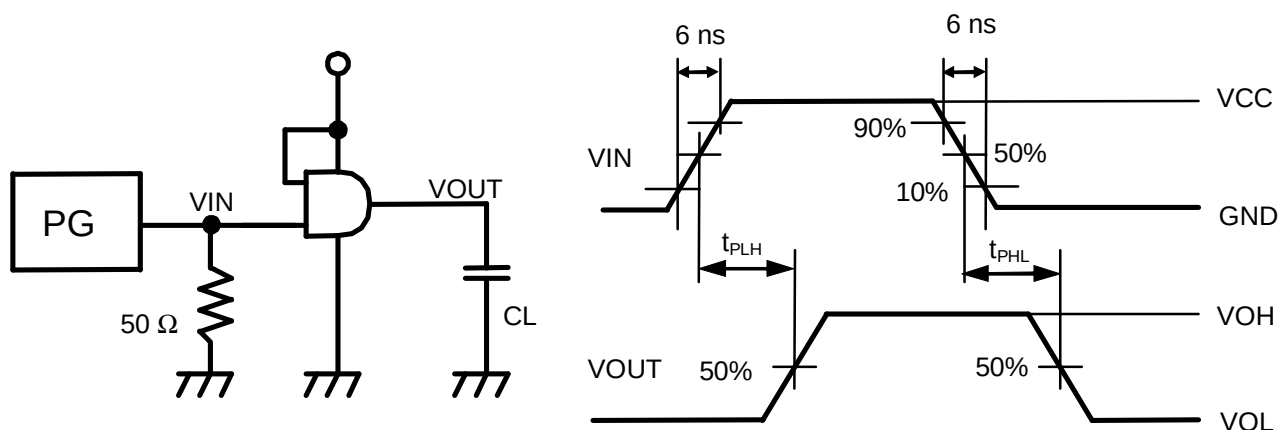
Item	Symbol	Measurement Conditions	Ta = 25°C			Ta = −40 to 85°C		Unit	
			VCC (V)	Min.	Typ.	Max.	Min.		Max.
Output rise / fall time	tTLH, tTHL	—	1.0	—	35	70	—	90	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Propagation delay time	tPLH, tPHL	—	1.0	—	30	60	—	75	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Input capacitance	CIN	—	—	5	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—	—	10	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.

Current consumption is averaged by the following equation.

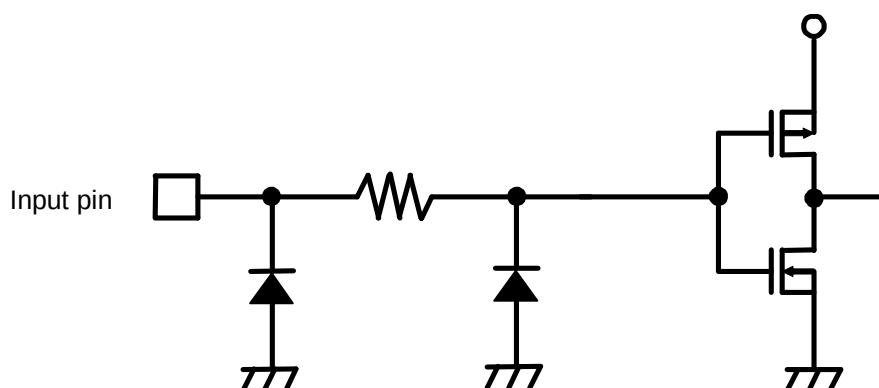
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75L14ANC is a SCHMITT INVERTER fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve operation by only a couple of batteries (1 to 3 V).

The internal circuitry has buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 3 V to 1 V and battery backup applications.

■ Features

- Wide power supply range: 1 V to 3.6 V
- Low current consumption: 1.0 μ A max. (at 3.6 V, 25°C)
- Typical propagation delay: $t_{PD} = 8$ ns (at 3 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

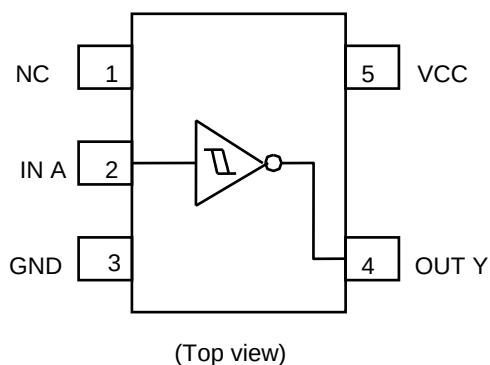
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

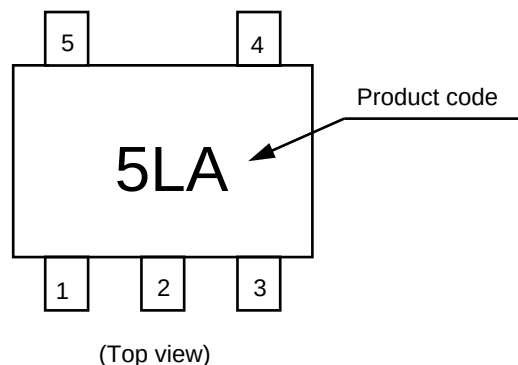
■ Package

- SC-88A

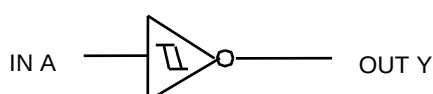
■ Pin Configuration



■ Marking Specification



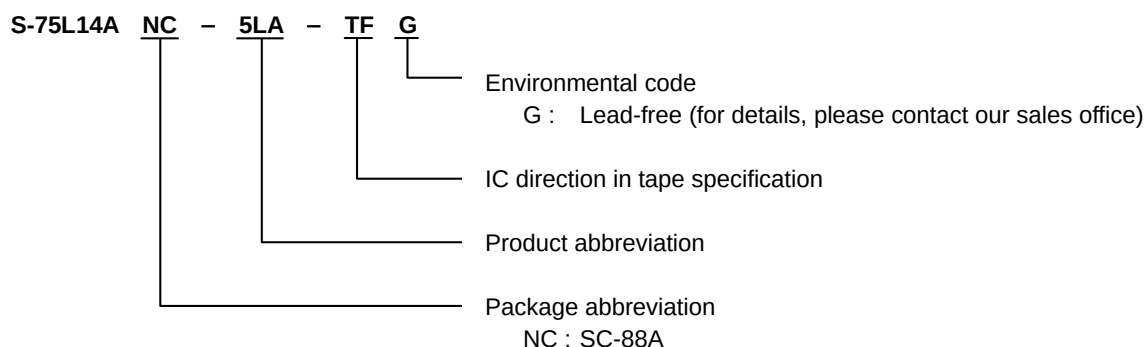
■ Logic Diagram



True values

A	Y
L	H
H	L

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +5.0	V
Input voltage	V_{IN}	-0.5 to +5.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±12.5	mA
V_{CC} /GND current	I_{CC}	±25	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

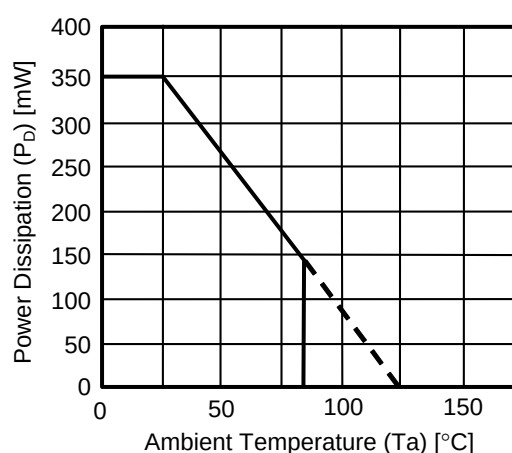
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	1 to 3.6	V
Input voltage	V_{IN}	0 to 3.6	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 1000 ($V_{CC} = 1.0$ V)	ns
		0 to 500 ($V_{CC} = 2.0$ V)	ns
		0 to 400 ($V_{CC} = 3.0$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit		
					V _{CC}	Min.	Typ.	Max.	Min.		Max.	
Input voltage	“H” level	V _{IH}	—		1.0	0.80	—	—	0.80	—	V	
					1.5	1.20	—	—	1.20	—	V	
					3.0	2.10	—	—	2.10	—	V	
	“L” level	V _{IL}	—		1.0	—	—	0.20	—	0.20	V	
					1.5	—	—	0.45	—	0.45	V	
					3.0	—	—	0.90	—	0.90	V	
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IL}	I _{OH} = −20 μA	1.0	0.9	1.0	—	0.9	—	V	
					1.5	1.4	1.5	—	1.4	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
				I _{OH} = −1 mA	1.5	1.07	1.23	—	0.99	—	V	
					I _{OH} = −2.6 mA	3.0	2.61	2.68	—	2.55	—	V
						“L” level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 20 μA	1.0	—	0
	1.5	—	0	0.1						—	0.1	V
	3.0	—	0	0.1	—					0.1	V	
	I _{OL} = 1 mA	1.5	—	0.23	0.31				—	0.37	V	
		I _{OL} = 2.6 mA	3.0	—	0.23				0.31	—	0.33	V
			Hysteresis Voltage	V _H	—				1.0	0.20	—	0.50
	1.5						0.25	—	0.50	—	—	V
3.0	0.45	—					0.65	—	—	V		
Input current		I _{IN}	V _{IN} = V _{CC} or GND	3.6	—	—	±0.1	—	±1.0	μA		
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	3.6	—	—	1.0	—	10.0	μA		

■ AC Electrical Characteristics

($C_L = 15$ pf, Input $t_R = t_F = 6$ ns, $V_{CC} = 3.3 \pm 0.3$ V, $T_a = 25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Measurement Conditions	Min.	Typ.	Max.	Unit
Output rise / fall time	t_{TLH} , t_{THL}	—	—	4.0	8.0	ns
Propagation delay time	t_{PLH} , t_{PHL}	—	—	4.0	10.5	ns

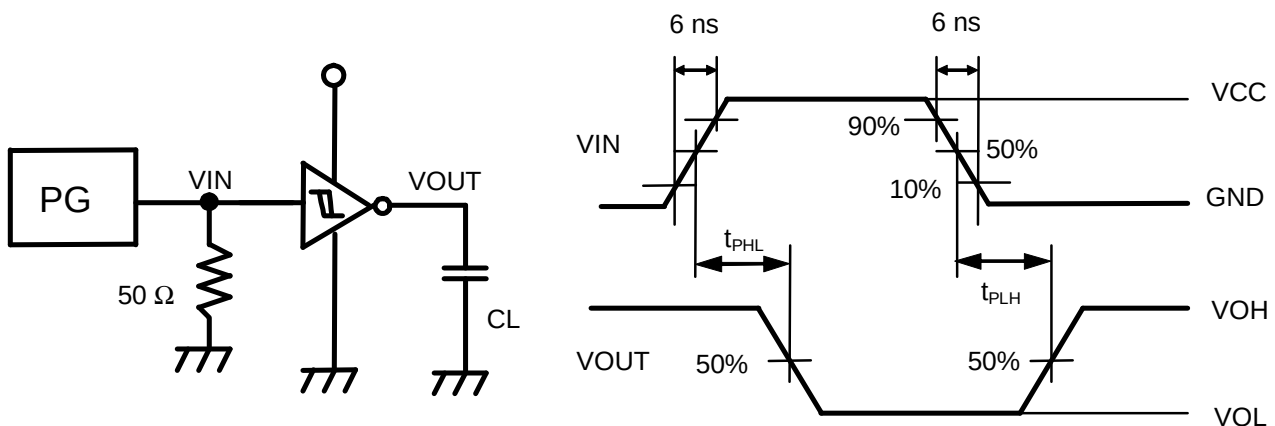
($C_L = 25$ pf, Input $t_R = t_F = 6$ ns unless otherwise specified)

Item	Symbol	Measurement Conditions	Ta = 25°C			Ta = −40 to 85°C		Unit	
			V _{CC} (V)	Min.	Typ.	Max.	Min.		Max.
Output rise / fall time	t _{TLH} , t _{THL}	—	1.0	—	35	70	—	90	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Propagation delay time	t _{PLH} , t _{PHL}	—	1.0	—	35	70	—	90	ns
			1.5	—	15	25	—	30	ns
			3.0	—	8	12	—	15	ns
Input capacitance	C _{IN}	—	—	5	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—	—	10	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

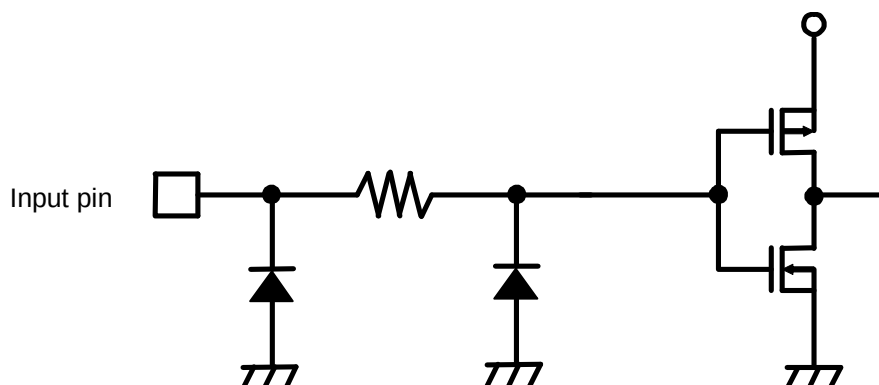
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times fin + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75L32ANC is a single 2-input OR gate fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve operation by only a couple of batteries (1 to 3 V).

The internal circuitry has buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 3 V to 1 V and battery backup applications.

■ Features

- Wide power supply range: 1 V to 3.6 V
- Low current consumption: 1.0 μ A max. (at 3.6 V, 25°C)
- Typical propagation delay: $t_{PD} = 7$ ns (at 3 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

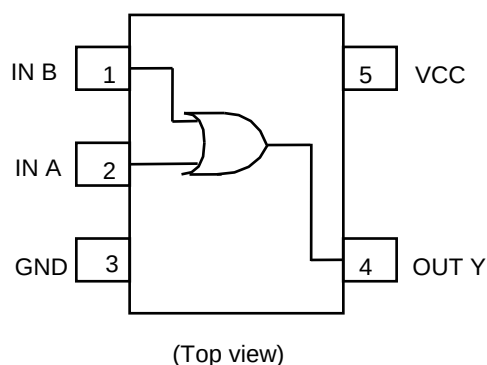
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

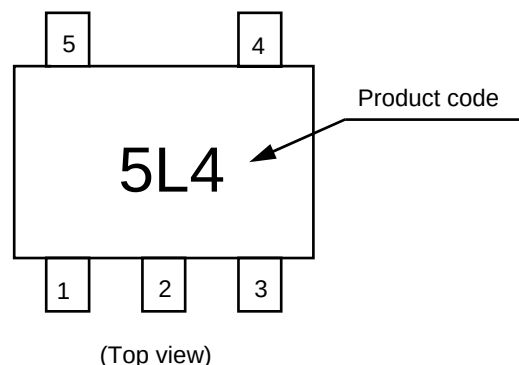
■ Package

- SC-88A

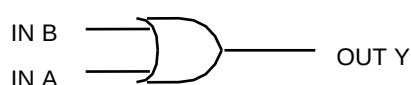
■ Pin Configuration



■ Marking Specification



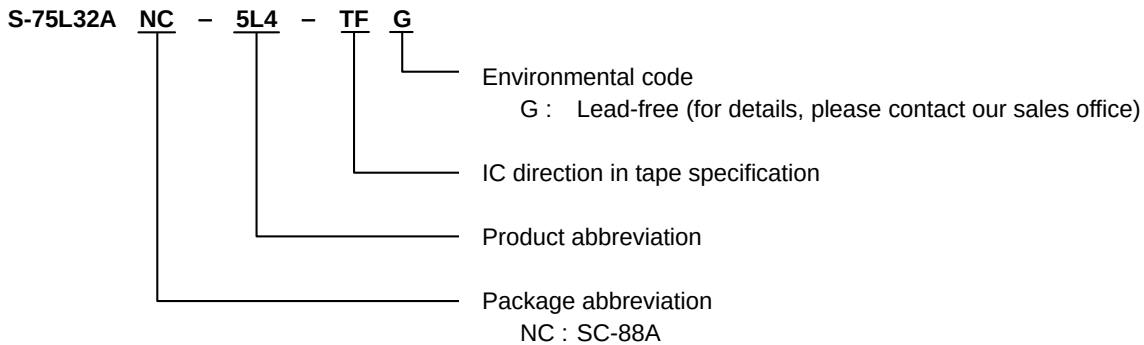
■ Logic Diagram



True values

A	B	Y
L	L	L
L	H	H
H	L	H
H	H	H

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +5.0	V
Input voltage	V_{IN}	-0.5 to +5.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±12.5	mA
V_{CC} /GND current	I_{CC}	±25	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

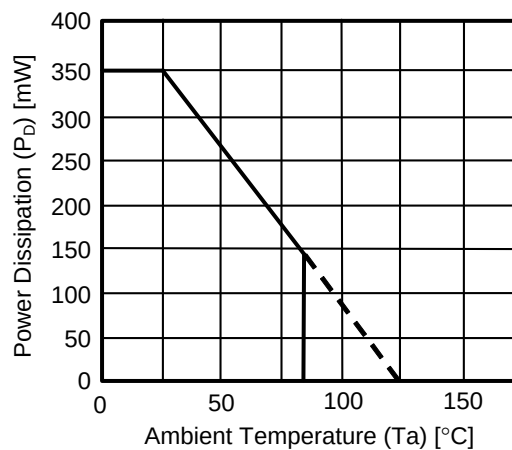
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	1 to 3.6	V
Input voltage	V_{IN}	0 to 3.6	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 1000 ($V_{CC} = 1.0$ V)	ns
		0 to 500 ($V_{CC} = 2.0$ V)	ns
		0 to 400 ($V_{CC} = 3.0$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit			
					V _{CC}	Min.	Typ.	Max.	Min.		Max.		
Input voltage	“H” level	V _{IH}	—	1.0	0.75	—	—	0.75	—	V			
				1.5	1.05	—	—	1.05	—	V			
				3.0	2.10	—	—	2.10	—	V			
	“L” level	V _{IL}	—	1.0	—	—	0.25	—	0.25	V			
				1.5	—	—	0.45	—	0.45	V			
				3.0	—	—	0.90	—	0.90	V			
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = −20 μA	1.0	0.9	1.0	—	0.9	—	V		
					1.5	1.4	1.5	—	1.4	—	V		
					3.0	2.9	3.0	—	2.9	—	V		
				I _{OH} = −1 mA	1.5	1.07	1.23	—	0.99	—	V		
					I _{OH} = −2.6 mA	3.0	2.61	2.68	—	2.55	—	V	
						“L” level	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 20 μA	1.0	—	0	0.1
	1.5	—	0	0.1						—	0.1	V	
	3.0	—	0	0.1	—					0.1	V		
	I _{OL} = 1 mA	1.5	—	0.23	0.31				—	0.37	V		
		I _{OL} = 2.6 mA	3.0	—	0.23				0.31	—	0.33	V	
			Input current		I _{IN}				V _{IN} = V _{CC} or GND		3.6	—	—
	Current consumption		I _{CC}	V _{IN} = V _{CC} or GND		3.6	—	—	1.0	—	10.0	μA	

■ AC Electrical Characteristics

($C_L = 15$ pf, Input $t_R = t_F = 6$ ns, $V_{CC} = 3.3 \pm 0.3$ V, $T_a = 25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Measurement Conditions	Min.	Typ.	Max.	Unit
Output rise / fall time	t_{TLH} , t_{THL}	—	—	4.0	8.0	ns
Propagation delay time	t_{PLH} , t_{PHL}	—	—	6.0	9.0	ns

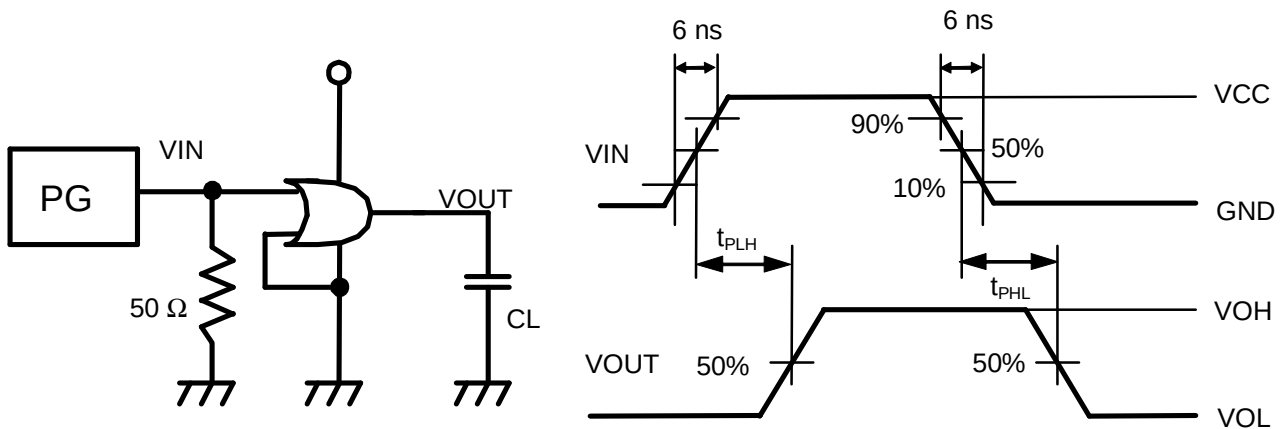
($C_L = 25$ pf, Input $t_R = t_F = 6$ ns unless otherwise specified)

Item	Symbol	Measurement Conditions	Ta = 25°C			Ta = −40 to 85°C		Unit	
			V _{CC} (V)	Min.	Typ.	Max.	Min.		Max.
Output rise / fall time	t _{TLH} , t _{THL}	—	1.0	—	35	70	—	90	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Propagation delay time	t _{PLH} , t _{PHL}	—	1.0	—	30	60	—	75	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Input capacitance	C _{IN}	—	—	5	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—	—	10	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

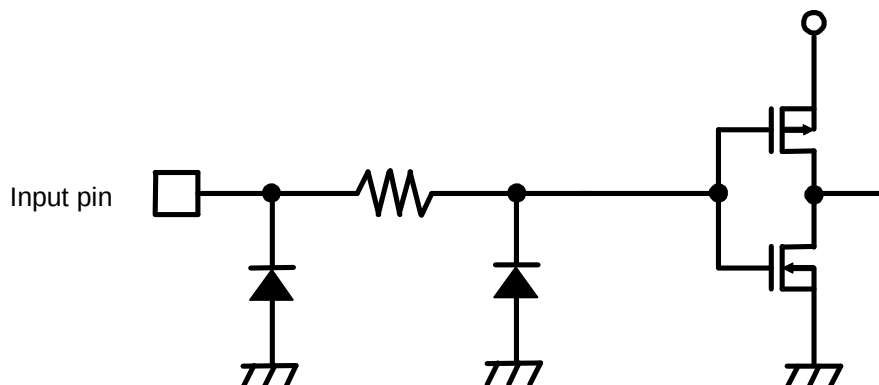
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times fin + I_{CC}$$

Measurement Circuit



Remark No-load output during measurement of current consumption.

■ Input Pin Equivalent Circuit



The S-75L86ANC is an EXCLUSIVE OR GATE fabricated by utilizing advanced silicon-gate CMOS technology which provides the inherent benefit of CMOS low power consumption to achieve operation by only a couple of batteries (1 to 3 V). The internal circuitry has buffered outputs to ensure high noise immunity and output stability.

Input voltage is allowed to be applied even if power voltage is not supplied because no diode is inserted between an input pin and V_{CC} .

This allows for interfaces between power supplies of different voltage, output level conversion from 3 V to 1 V and battery backup applications.

■ Features

- Wide power supply range: 1 V to 3.6 V
- Low current consumption: 1.0 μ A max. (at 3.6 V, 25°C)
- Typical propagation delay: $t_{PD} = 7$ ns (at 3 V)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ min.
- Power down protection: All pins
- Lead-free

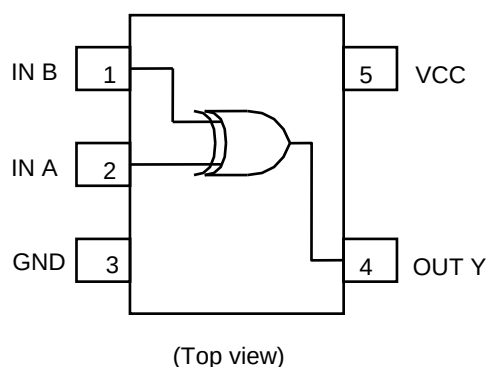
■ Applications

- Personal computers, peripherals
- Cellular phones
- Cameras
- Games

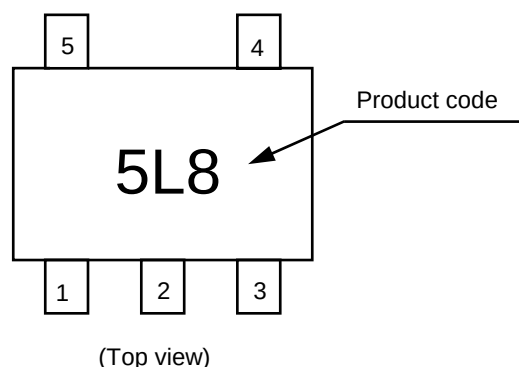
■ Package

- SC-88A

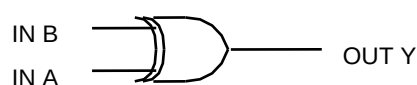
■ Pin Configuration



■ Marking Specification



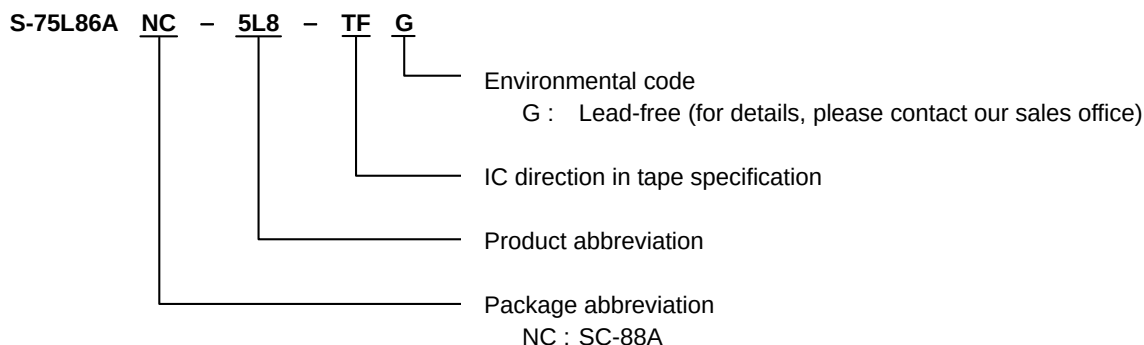
■ Logic Diagram



True values

A	B	Y
L	L	L
L	H	H
H	L	H
H	H	L

■ Product Name Structure



■ Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

Item	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{CC}	-0.5 to +5.0	V
Input voltage	V_{IN}	-0.5 to +5.0	V
Output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input parasitic diode current	I_{IK}	-20	mA
Output parasitic diode current	I_{OK}	±20	mA
Output current	I_{OUT}	±12.5	mA
V_{CC} /GND current	I_{CC}	±25	mA
Power dissipation	P_D	200 (When not mounted on board)	mW
		350 ^{*1}	mW
Operating ambient temperature	T_{opr}	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C
Lead temperature (10 s)	T_L	260	°C

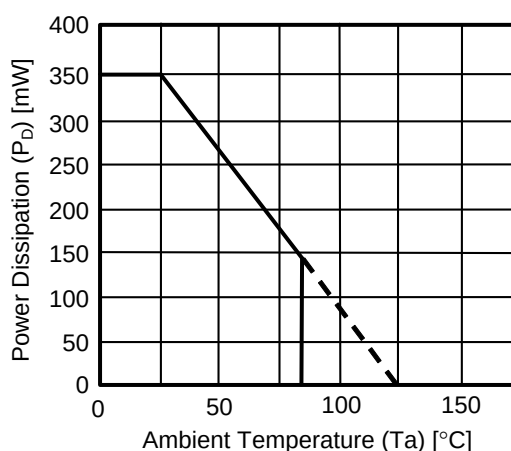
*1. When mounted on board

[Mounted board]

(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



Power Dissipation of Package (When Mounted on Board)

■ Recommended Operating Conditions

Item	Symbol	Standard	Unit
Power voltage	V_{CC}	1 to 3.6	V
Input voltage	V_{IN}	0 to 3.6	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Input rise / fall time	t_R, t_F	0 to 1000 ($V_{CC} = 1.0$ V)	ns
		0 to 500 ($V_{CC} = 2.0$ V)	ns
		0 to 400 ($V_{CC} = 3.0$ V)	ns

■ DC Electrical Characteristics

Item		Symbol	Conditions		Ta = 25°C			Ta = −40 to 85°C		Unit		
					V _{CC}	Min.	Typ.	Max.	Min.		Max.	
Input voltage	“H” level	V _{IH}	—	1.0	0.75	—	—	0.75	—	V		
				1.5	1.05	—	—	1.05	—	V		
				3.0	2.10	—	—	2.10	—	V		
	“L” level	V _{IL}	—	1.0	—	—	0.25	—	0.25	V		
				1.5	—	—	0.45	—	0.45	V		
				3.0	—	—	0.90	—	0.90	V		
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = −20 μA	1.0	0.9	1.0	—	0.9	—	V	
					1.5	1.4	1.5	—	1.4	—	V	
					3.0	2.9	3.0	—	2.9	—	V	
				I _{OH} = −1 mA	1.5	1.07	1.23	—	0.99	—	V	
					I _{OH} = −2.6 mA	3.0	2.61	2.68	—	2.55	—	V
	“L” level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	1.0	—	0	0.1	—	0.1	V	
					1.5	—	0	0.1	—	0.1	V	
					3.0	—	0	0.1	—	0.1	V	
				I _{OL} = 1 mA	1.5	—	0.23	0.31	—	0.37	V	
					I _{OL} = 2.6 mA	3.0	—	0.23	0.31	—	0.33	V
Input current		I _{IN}	V _{IN} = V _{CC} or GND	3.6	—	—	±0.1	—	±1.0	μA		
Current consumption		I _{CC}	V _{IN} = V _{CC} or GND	3.6	—	—	1.0	—	10.0	μA		

■ AC Electrical Characteristics

($C_L = 15$ pf, Input $t_R = t_F = 6$ ns, $V_{CC} = 3.3 \pm 0.3$ V, $T_a = 25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Measurement Conditions	Min.	Typ.	Max.	Unit
Output rise / fall time	t_{TLH} , t_{THL}	—	—	4.0	8.0	ns
Propagation delay time	t_{PLH} , t_{PHL}	—	—	6.0	9.0	ns

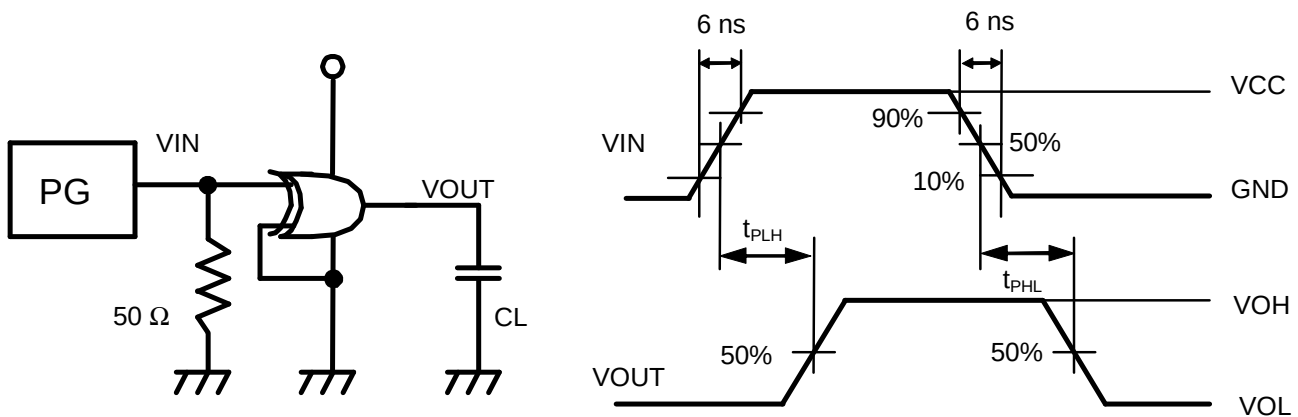
($C_L = 25$ pf, Input $t_R = t_F = 6$ ns unless otherwise specified)

Item	Symbol	Measurement Conditions	Ta = 25°C			Ta = −40 to 85°C		Unit	
			V _{CC} (V)	Min.	Typ.	Max.	Min.		Max.
Output rise / fall time	t _{TLH} , t _{THL}	—	1.0	—	35	70	—	90	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Propagation delay time	t _{PLH} , t _{PHL}	—	1.0	—	30	60	—	75	ns
			1.5	—	15	25	—	30	ns
			3.0	—	7	10	—	14	ns
Input capacitance	C _{IN}	—	—	5	10	—	10	pF	
Equivalent internal capacitance	C _{PD} ^{*1}	—	—	10	—	—	—	pF	

*1. C_{PD} is the no-load equivalent capacitance inside the circuitry. Refer to the measurement circuit shown below.
Current consumption is averaged by the following equation.

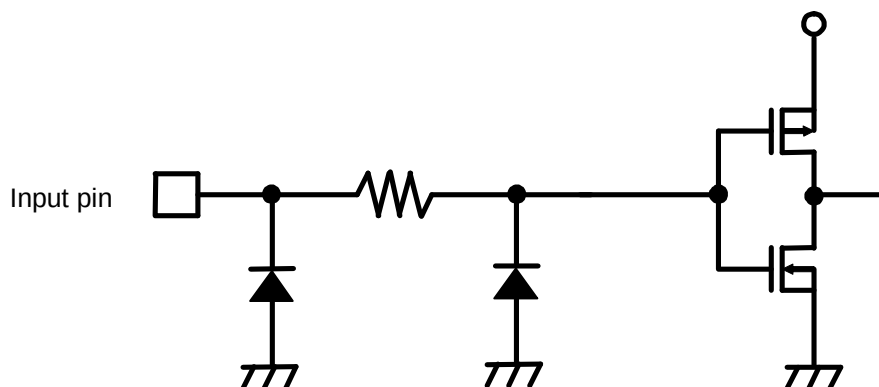
$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC}$$

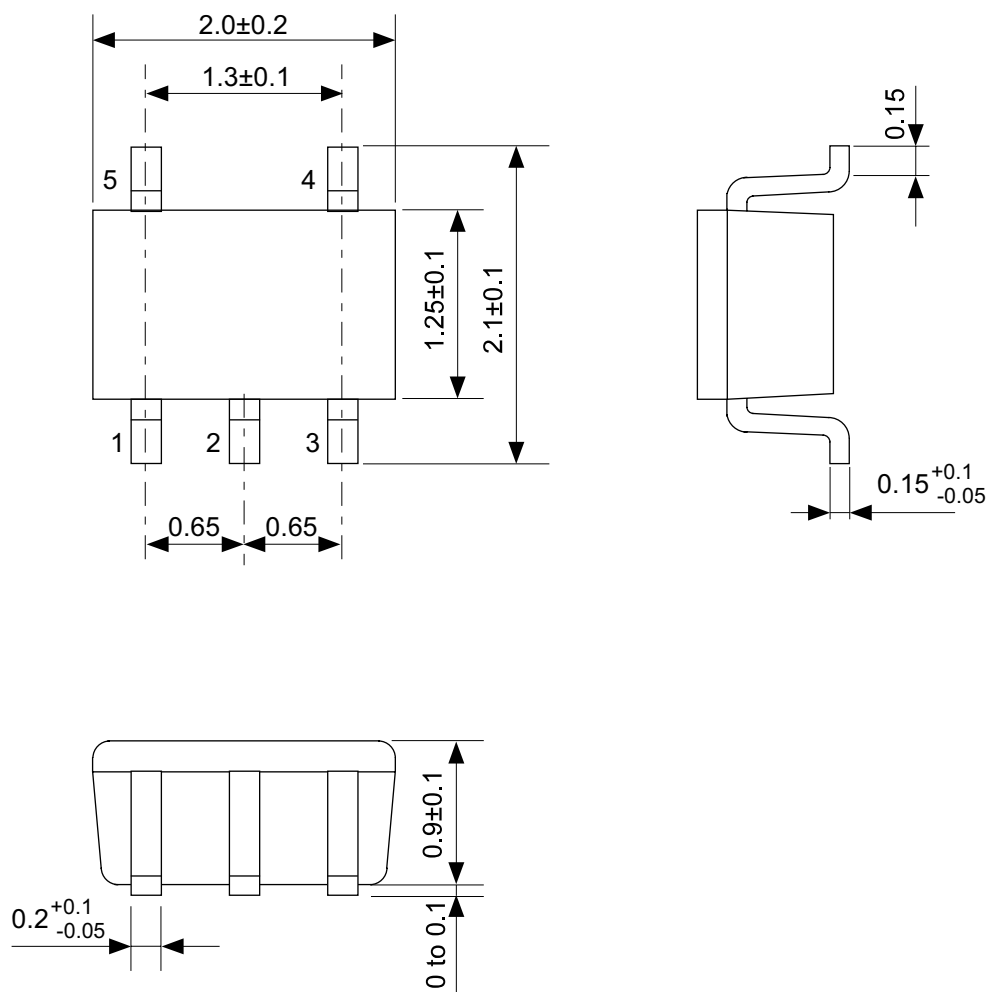
Measurement Circuit



Remark No-load output during measurement of current consumption.

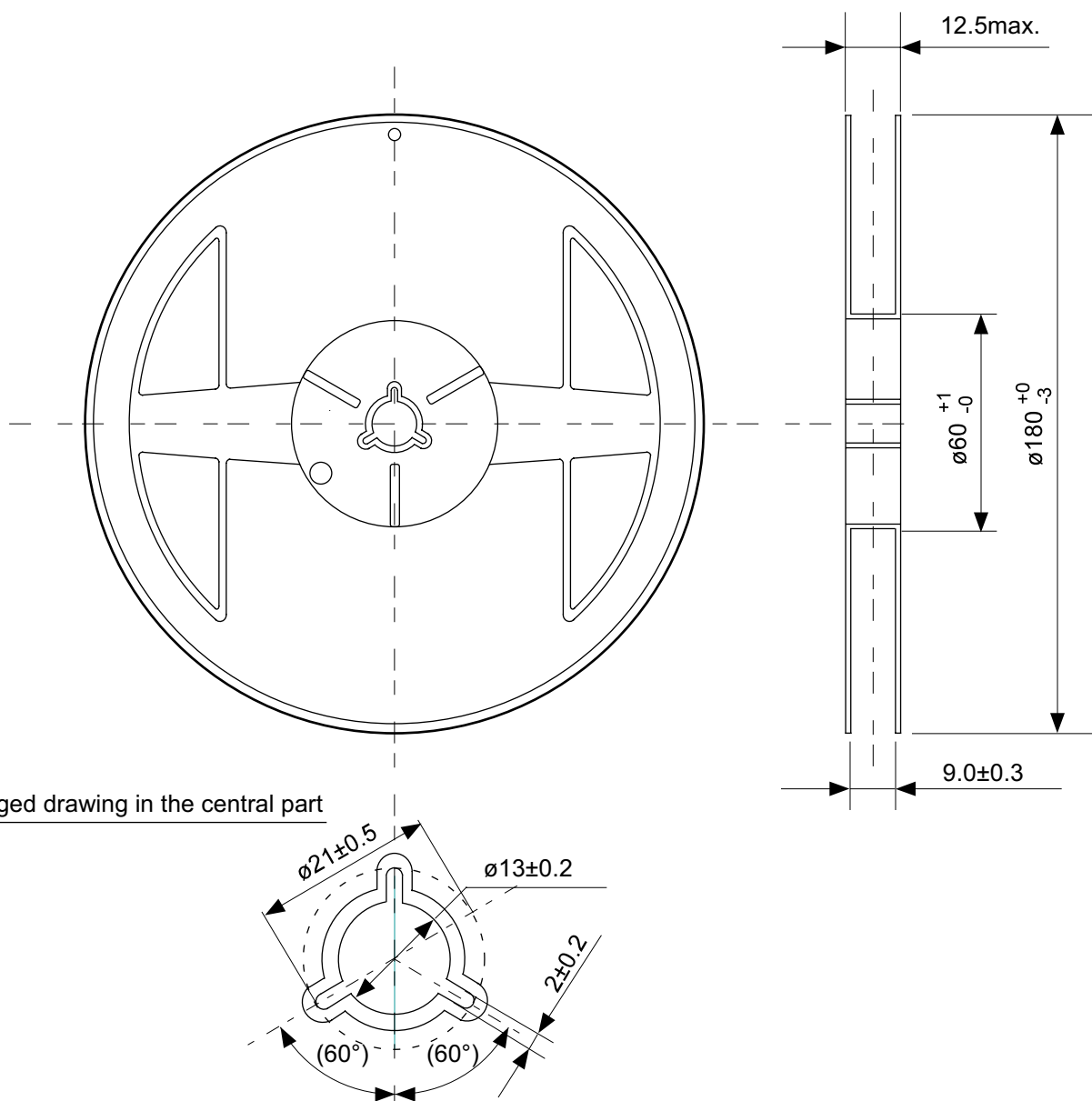
■ Input Pin Equivalent Circuit





No. NP005-B-P-SD-1.1

TITLE	SC88A-B-PKG Dimensions
No.	NP005-B-P-SD-1.1
SCALE	
UNIT	mm
Seiko Instruments Inc.	



No. NP005-B-R-SD-2.1

TITLE	SC88A-B-Reel		
No.	NP005-B-R-SD-2.1		
SCALE		QTY.	3000
UNIT	mm		
Seiko Instruments Inc.			



Seiko Instruments Inc.
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